



CHILISIN ELECTRONICS CORP.
Total Solution Provider for EMI, Power and RF.

Chilisin Electronics Corp.

Product Overview 2012



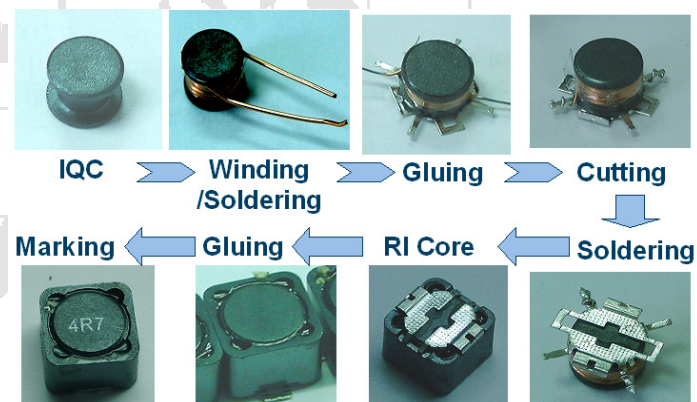
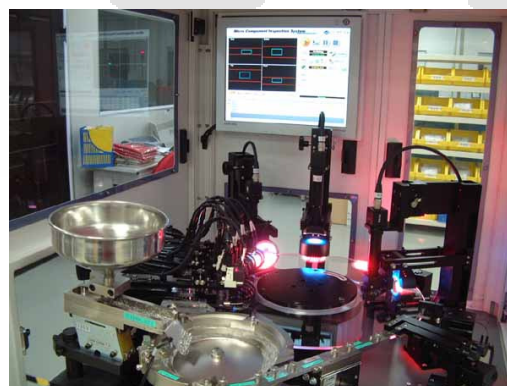
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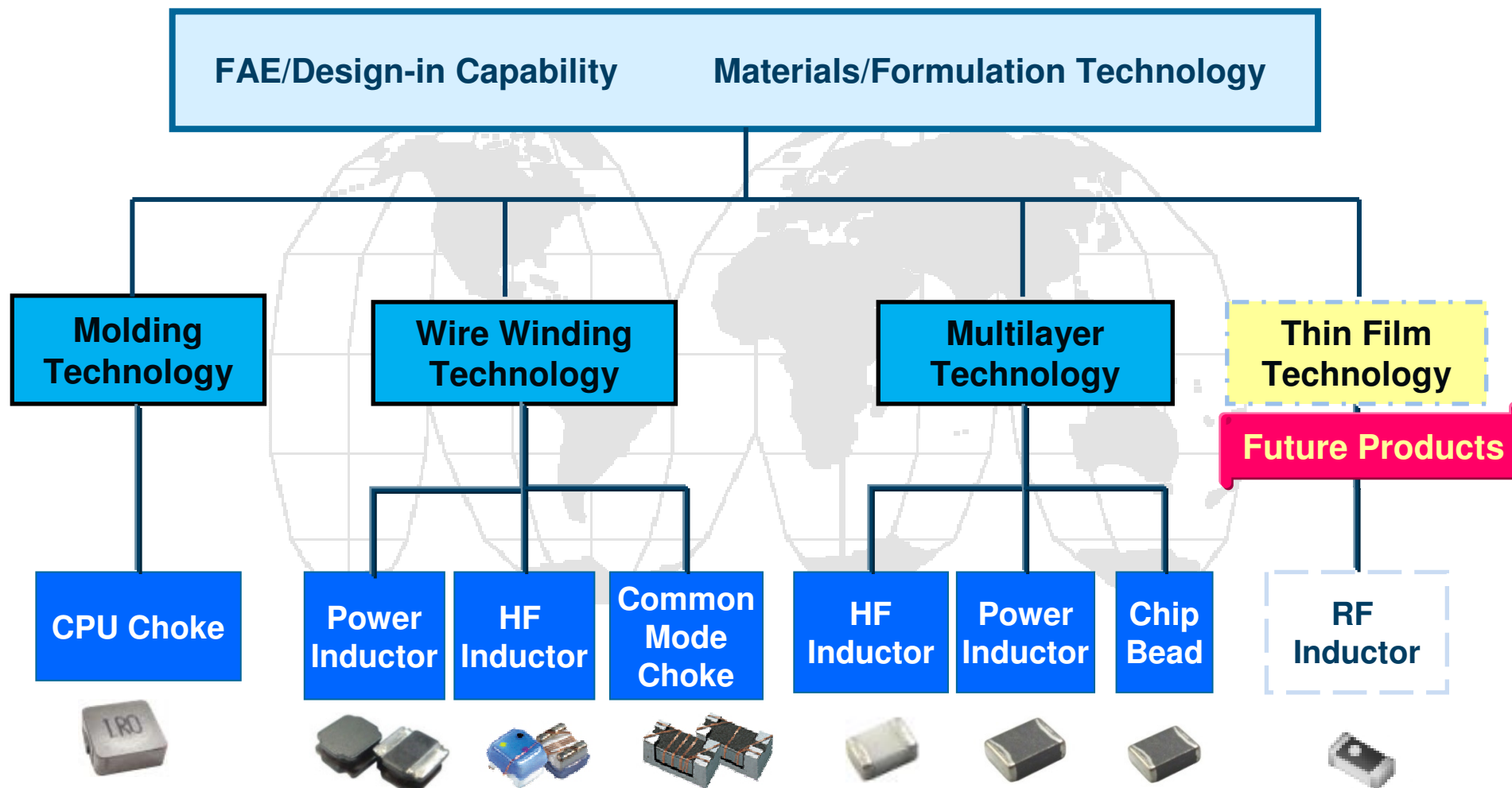


Vertically Integrated

- ◆ In-house Powder Mixing
- ◆ In-house Ferrite and Ceramic core manufacturing.
- ◆ In-house Automated and Manual wire winding
- ◆ In-house Thick/Thin film capabilities
- ◆ In-house Metal Powder Molding



Core Technology



Comprehensive Product Range

SMD Series

- Multilayer Power Inductor
- Multilayer Chip Inductor
- Multilayer Chip Beads
- Thin Film RF Inductor
- 1210 USB3.0 CMM
- 0805 USB2.0 CMM
- 0805 HDMI CMM
- RF Chip Wound Inductor
- SMD Power Inductor, LVS/F
- SMD Molding Choke



Coil Series

- Power Line EMI Filter
- Toroidal Series
- Leadless Power Inductor



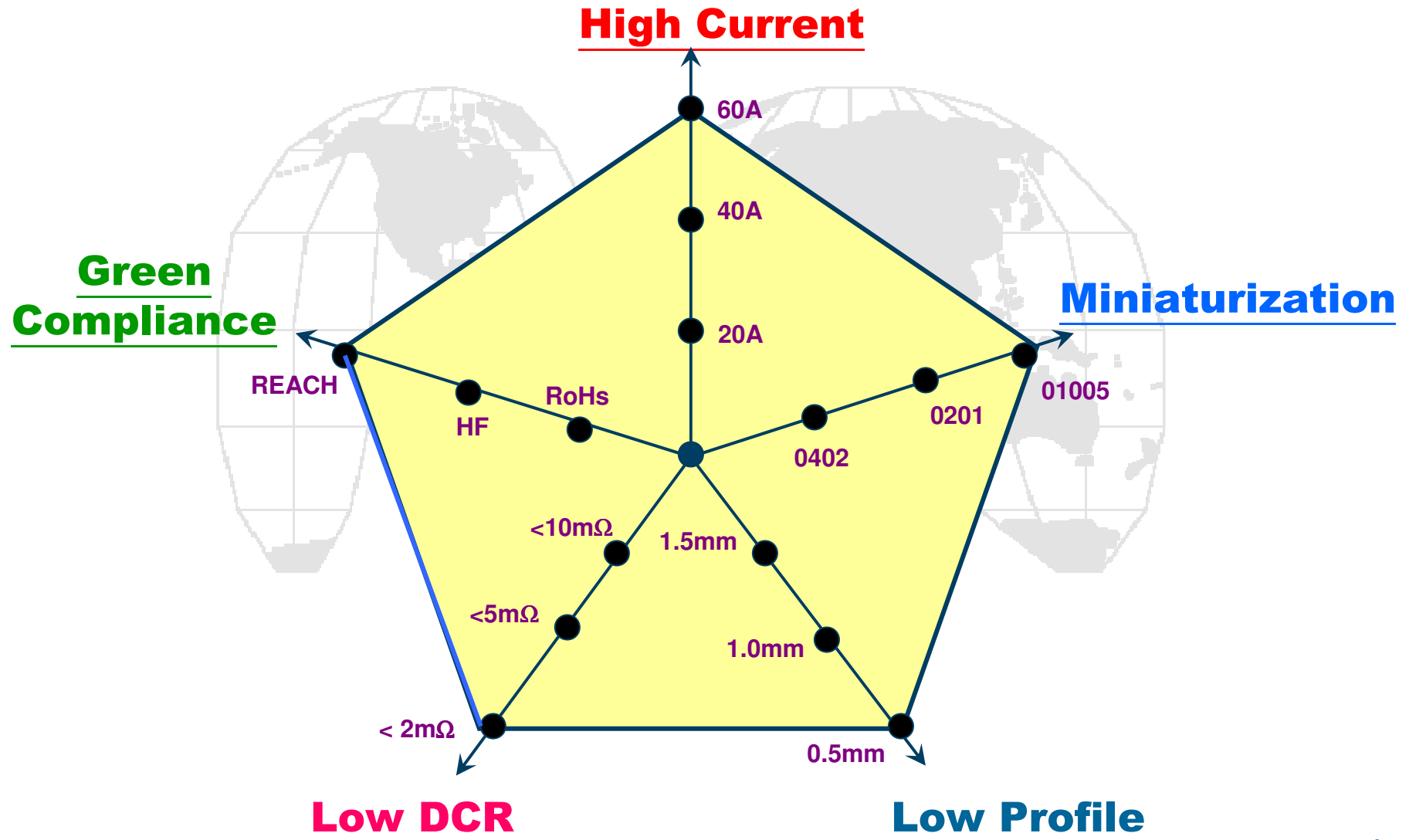
Soft Ferrite Core Series

- Ni-Zn Series EMI Filter
- Iron/Ferrite Toroid
- In-House Ferrite Core



Comparable to Vishay, CoilCraft, Murata, TDK, Taiyo Yuden, Sumida....

Trend of Product Development





CHILISIN ELECTRONICS CORP.
Total Solution Provider for EMI, Power and RF.

One Stop Shop

Inductor turn-key solution : EMI, Power & RF components

◆ EMI / EMC

Chip Beads

- General (<1GHz)
- Hi-Speed (~1GHz)
- GHz (>1GHz)
- Power (~6A)

Common Mode Choke

- USB2.0 (480 M bit/s)
- HDMI (3 G bit/s)
- USB3.0(5 G bit/s)

◆ D-D Converter

Power Inductor

- Multilayer (500mA-1.5A)
- Magnetic Resin (1A-7A)
- Molded Design (2A-50A)

◆ RF

HF Chip Inductor @500MHz

- **Wire Wound**
(Q Up to 80, SRF Up to 18GHz)
- **Multilayer**
(Q Up to 18, SRF Up to 10GHz)
- **Thin Film**
(Q >12. SRF up to 6GHz)

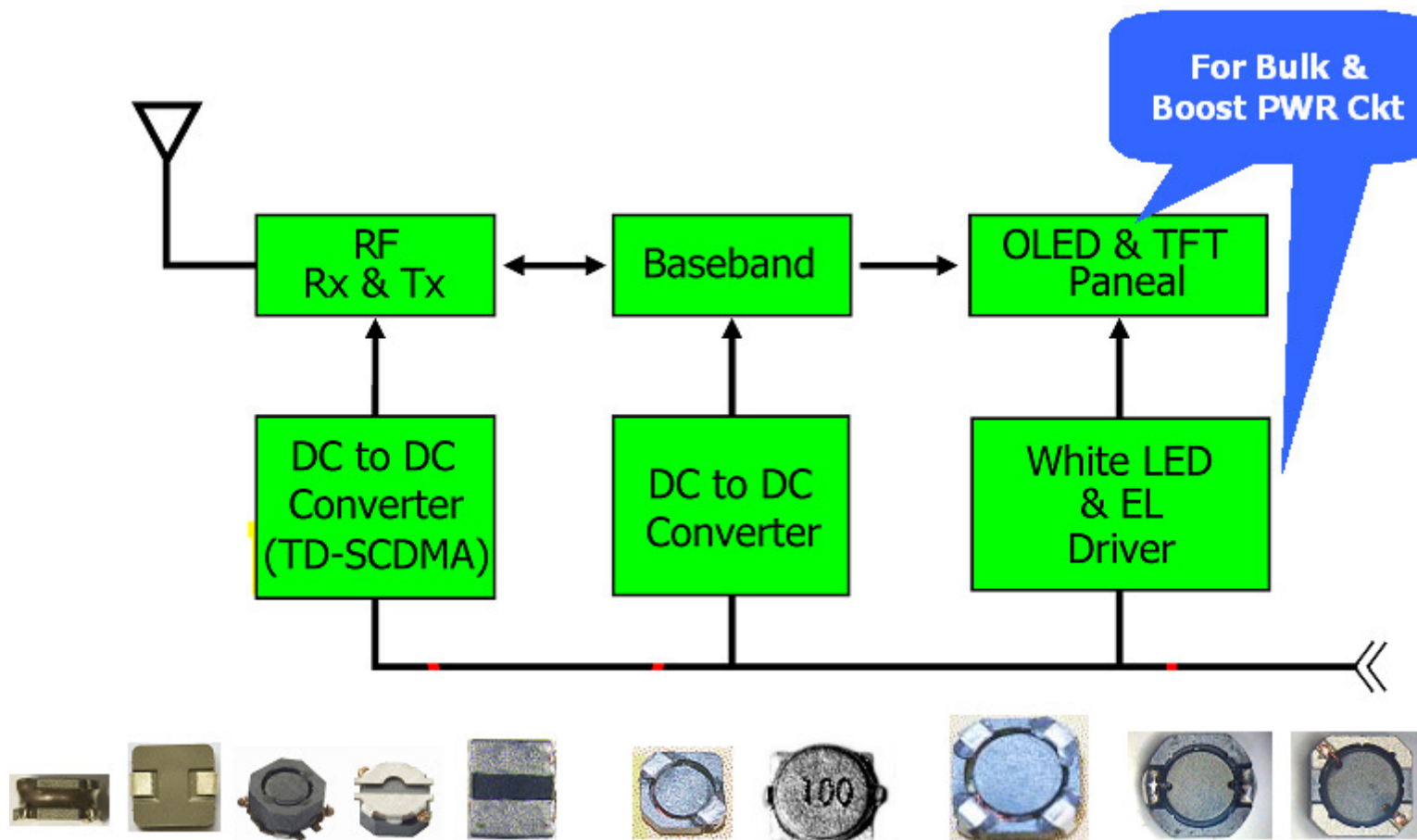


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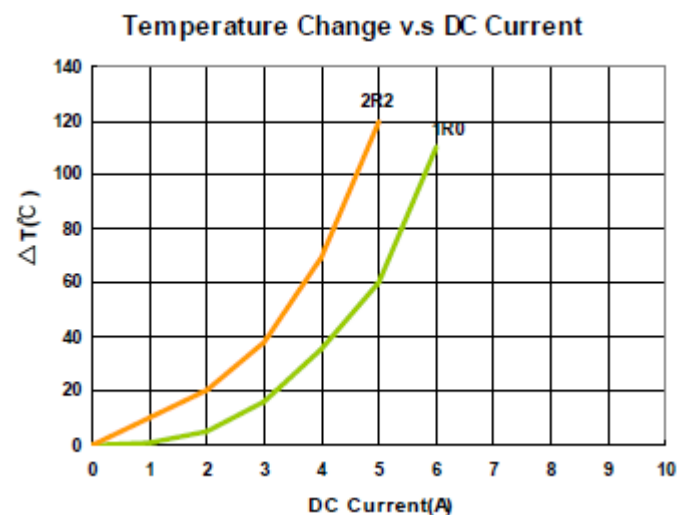
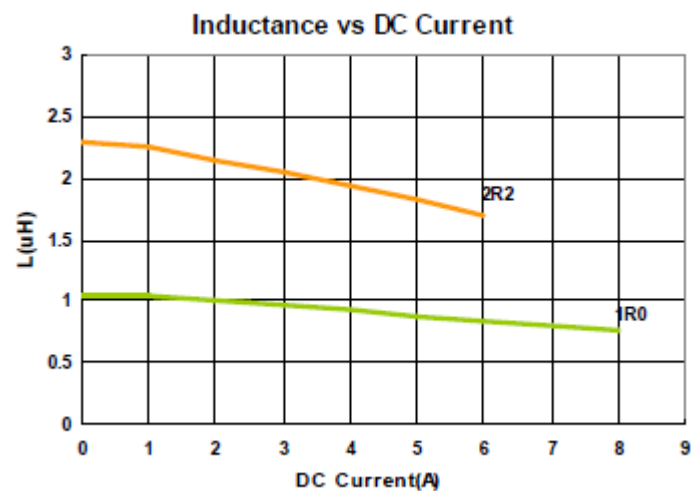


Power Solutions



Power Inductors

- ◆ Shielded and Unshielded
- ◆ Current ratings up to 50A
 - Irms – X° temp rise
 - Isat – X% drop in L
- ◆ 2.0 x 1.5 x 0.55 (MP) to 16 x 22 x 8 (SSL)
- ◆ RoHs and Halogen free
- ◆ Magnetic Resin, Molding technologies, & Multilayer



Miniature Multilayer Power Inductors

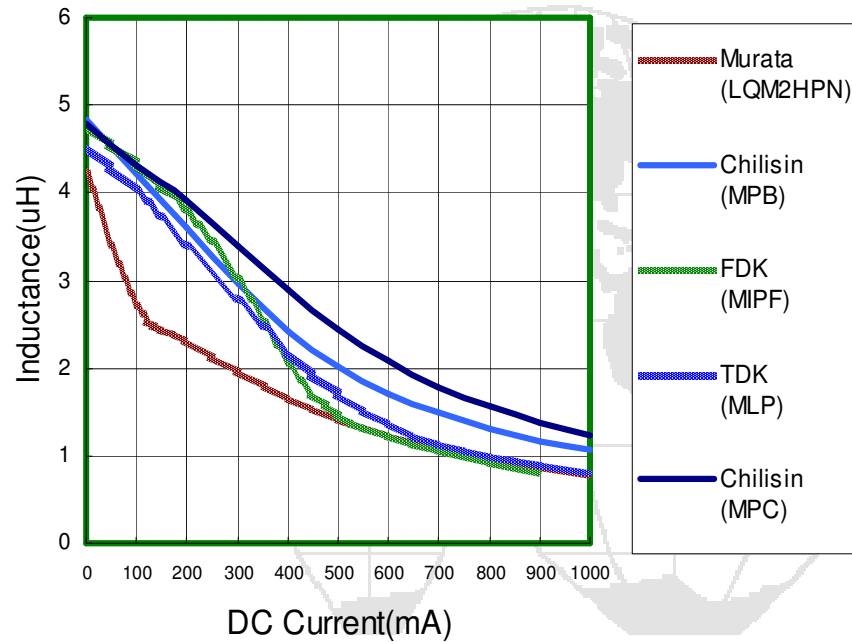
- ◆ MPA (initial series)
 - 1.6 x 0.8 x 0.8
 - 500mA – 700mA
 - 0.35 – 0.55 mOhms
- ◆ MPB (Low resistance, higher current ratings)
 - 1.6 x 0.8 x 0.8
 - 600mA – 1.8A
 - 0.04 - 0.40 mOhms
- ◆ MPC (High Sat Current, higher DCR)
 - 2.0 x 1.25 x 1.0
 - 600mA – 1.6A
 - 0.07 – 0.32 mOhms



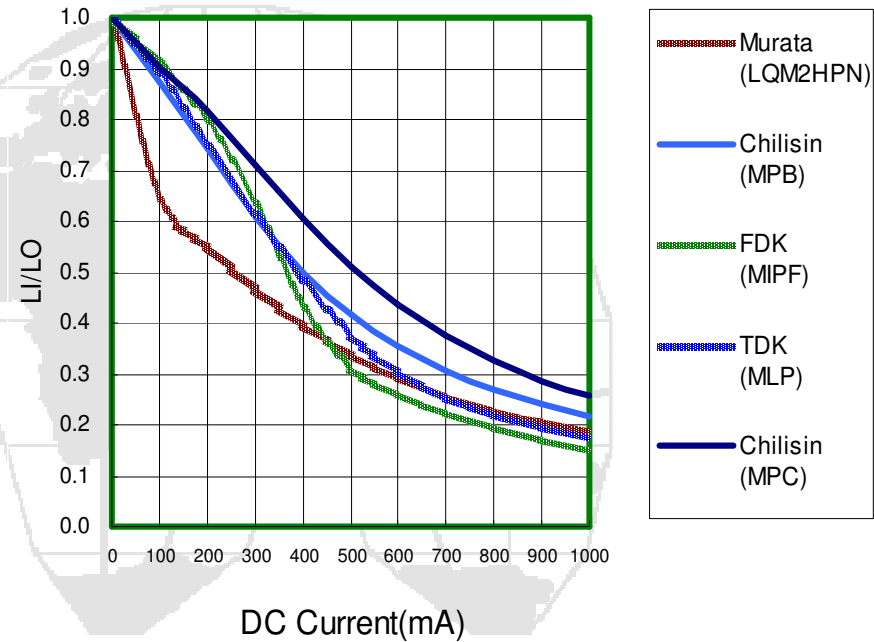
Characteristic Comparison

DC current characteristics

252010-4R7



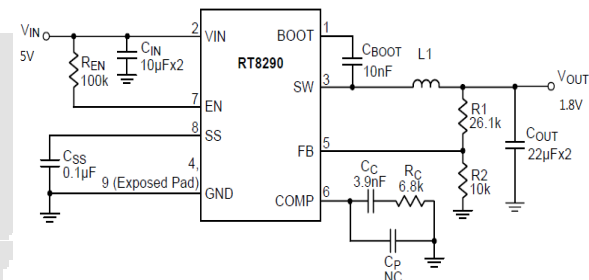
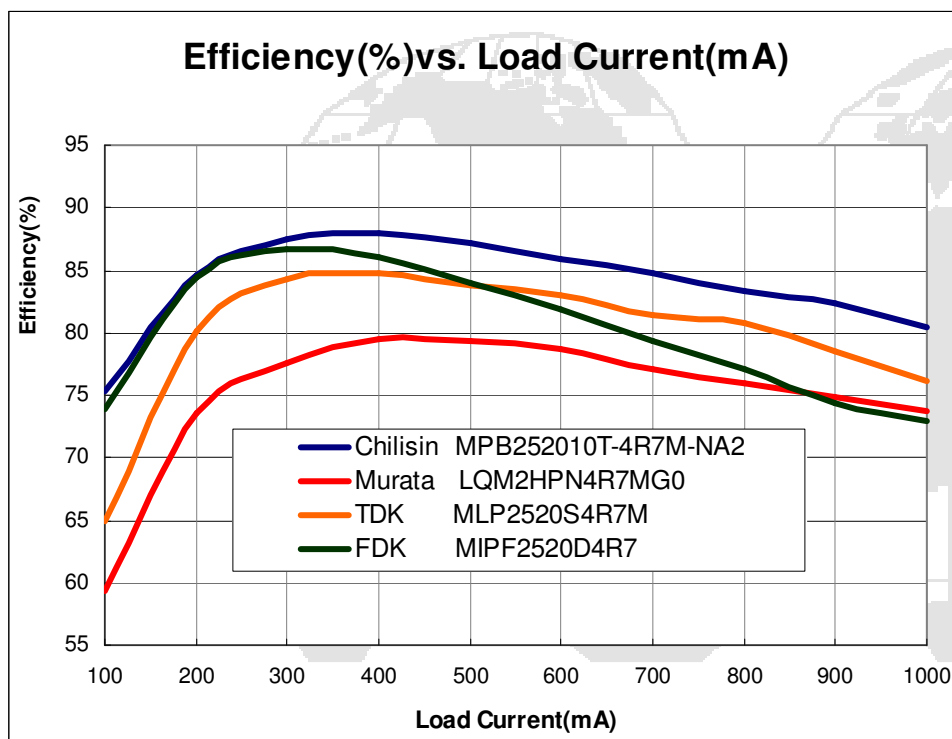
252010-4R7



Our products still have better saturation current, especially for MPC series.

Characteristic Comparison

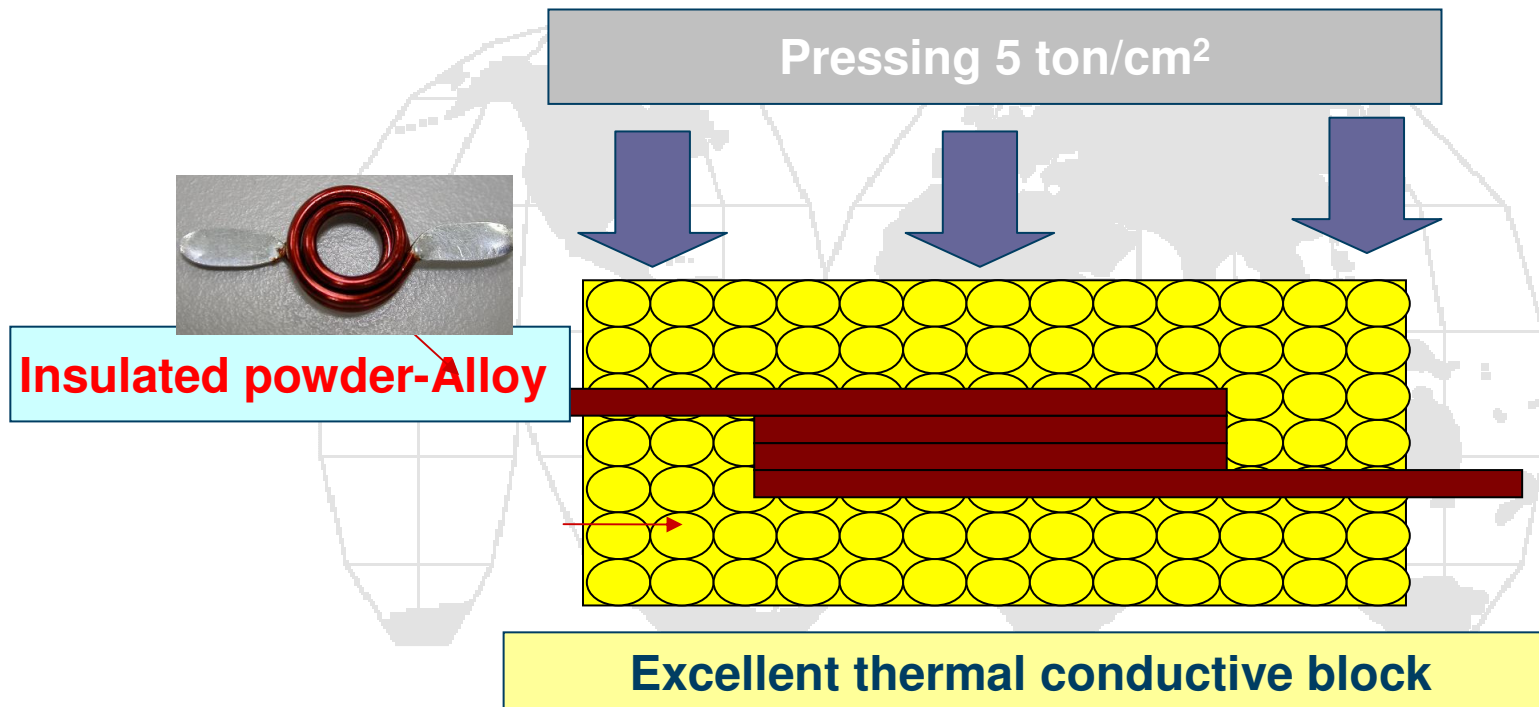
Efficiency Data



EVB:
Richtek RT8290 ,
Step Down Converter 5V To 1.8V

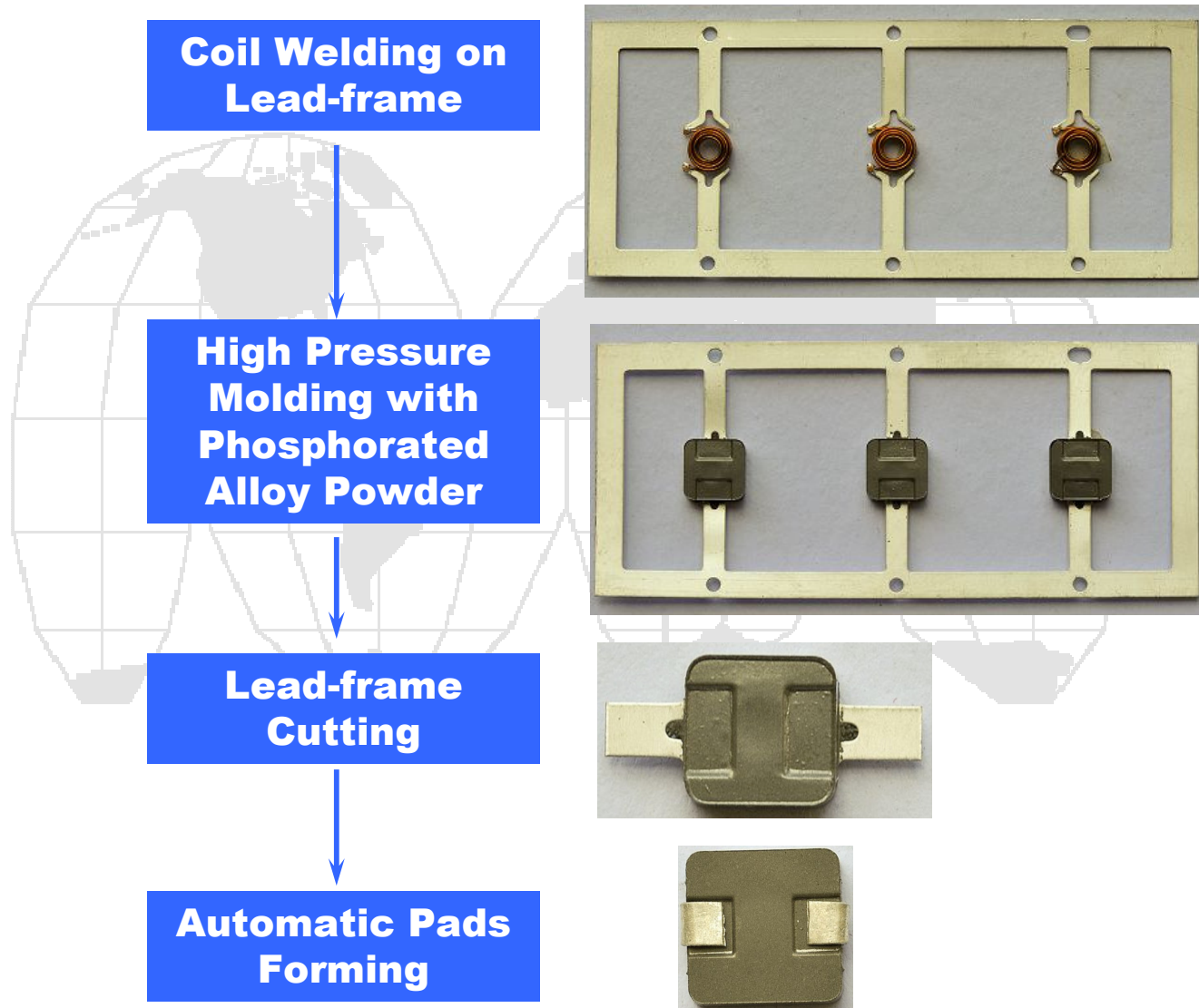
Our products still have better efficiency,

Ultra High Current Power Choke



- Low core loss
- Minimize buzzing noise
- Shielded design
- No coating and rusty reliability issue
- Better body strength and thermal property
- Reliable automatic process for mass production
- 4.1 x 4.6 x 1.2
- Up to 37A

Process of Molding MHC/MHCI

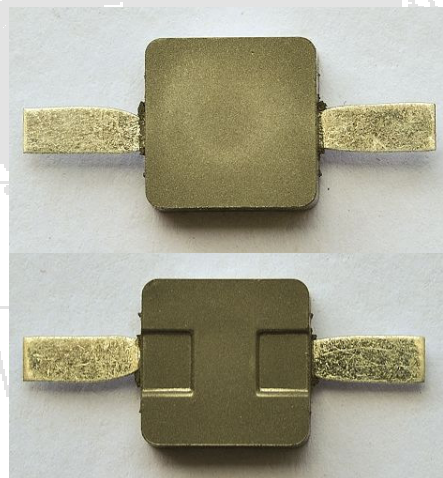


Process of Molding MHC/MHCI (Big Wire)

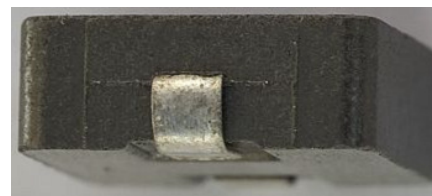
**Coil Winding &
Pads Soldering**



**High Pressure
Molding with
Phosphorated
Alloy Powder**

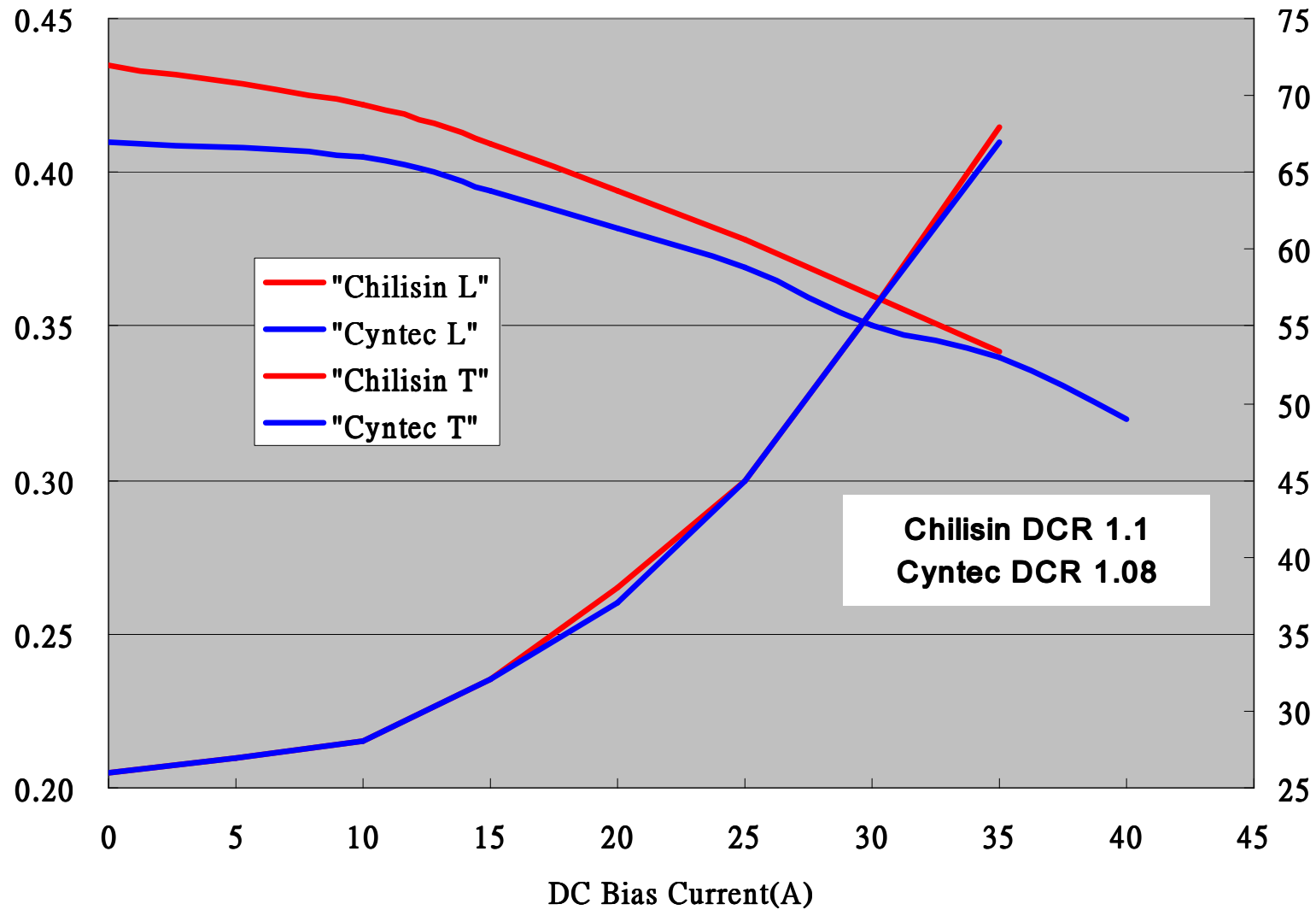


**Automatic Pads
Forming**



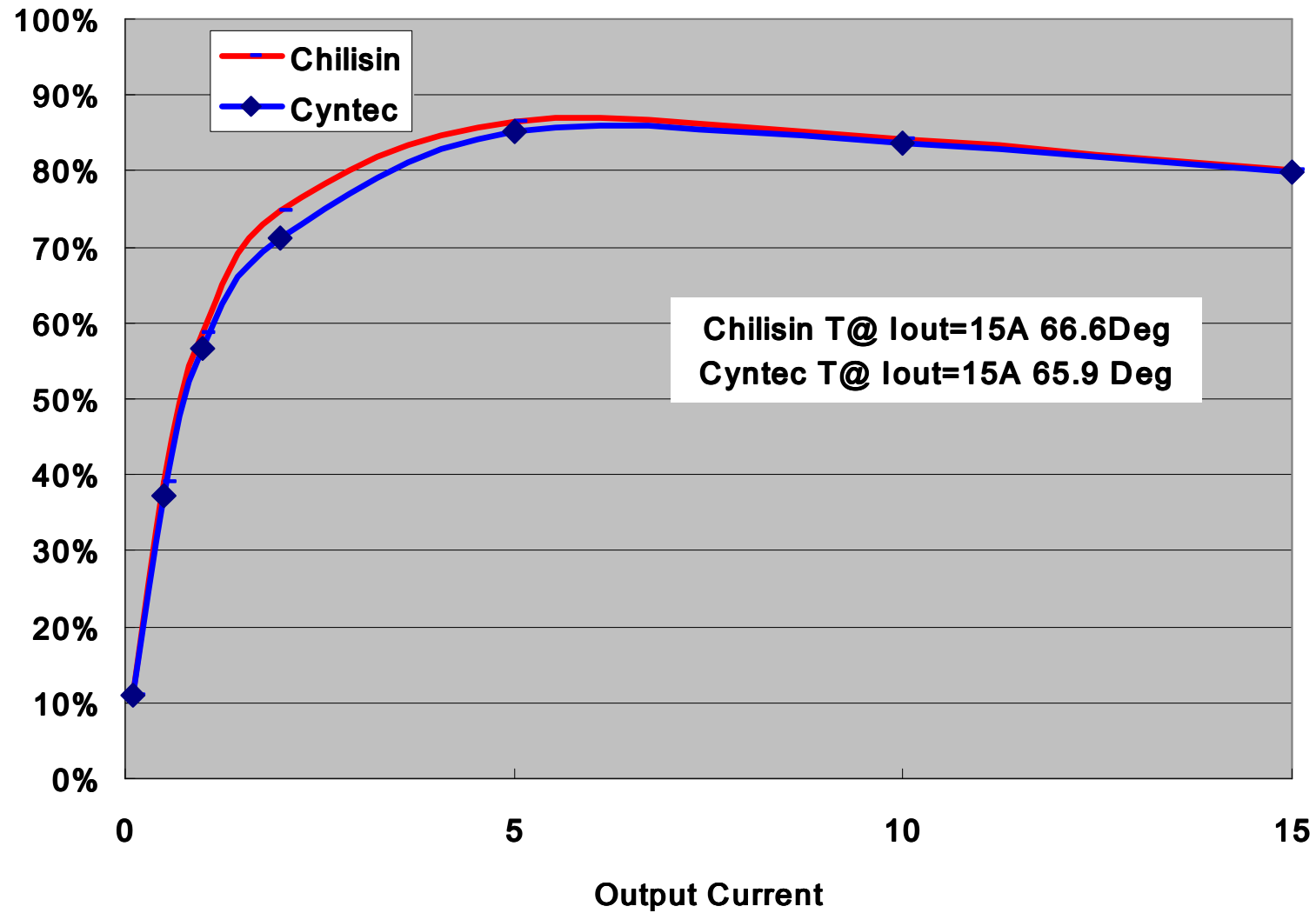


Performance of Chilisin MHCC

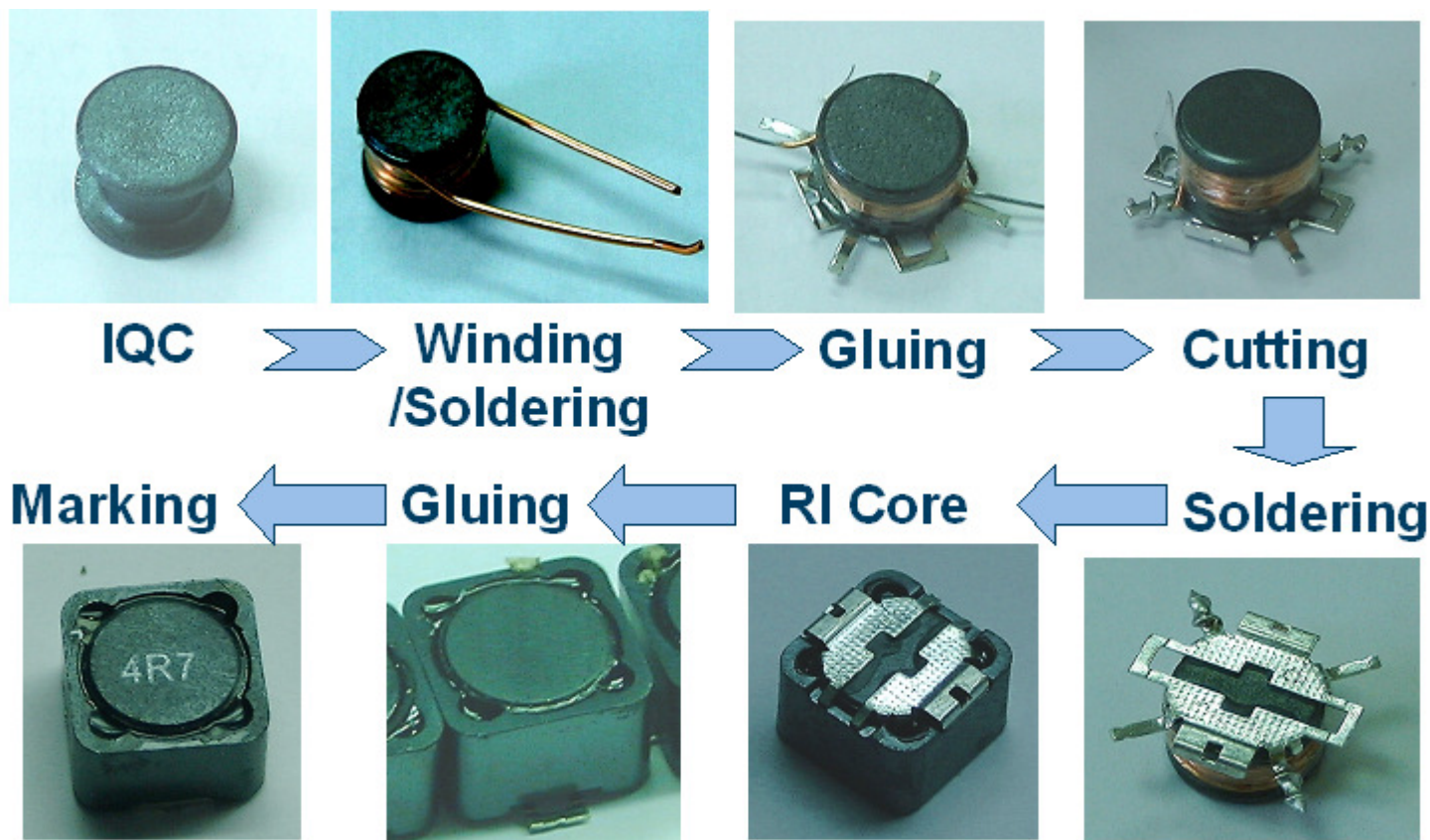




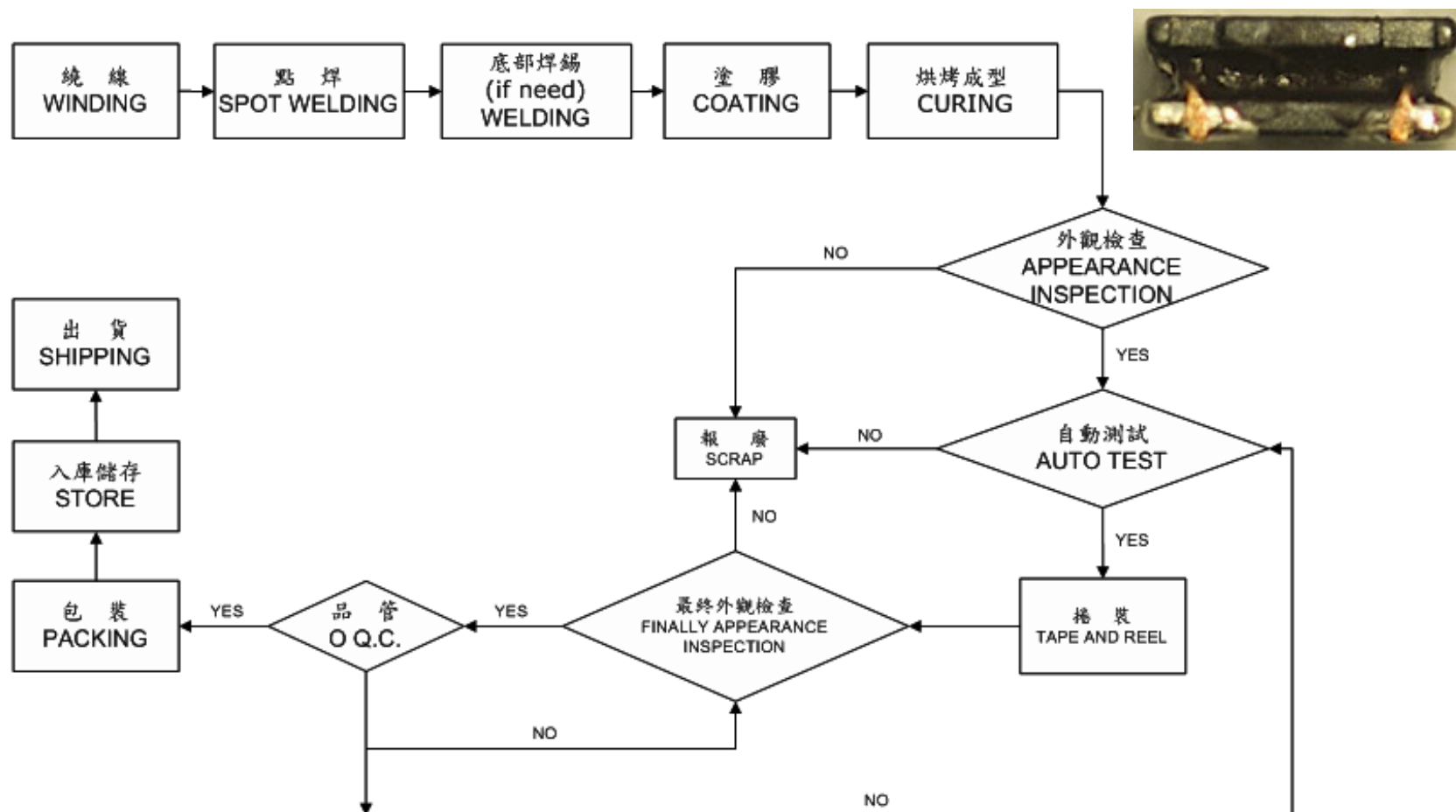
Performance of Chilisin MHCC



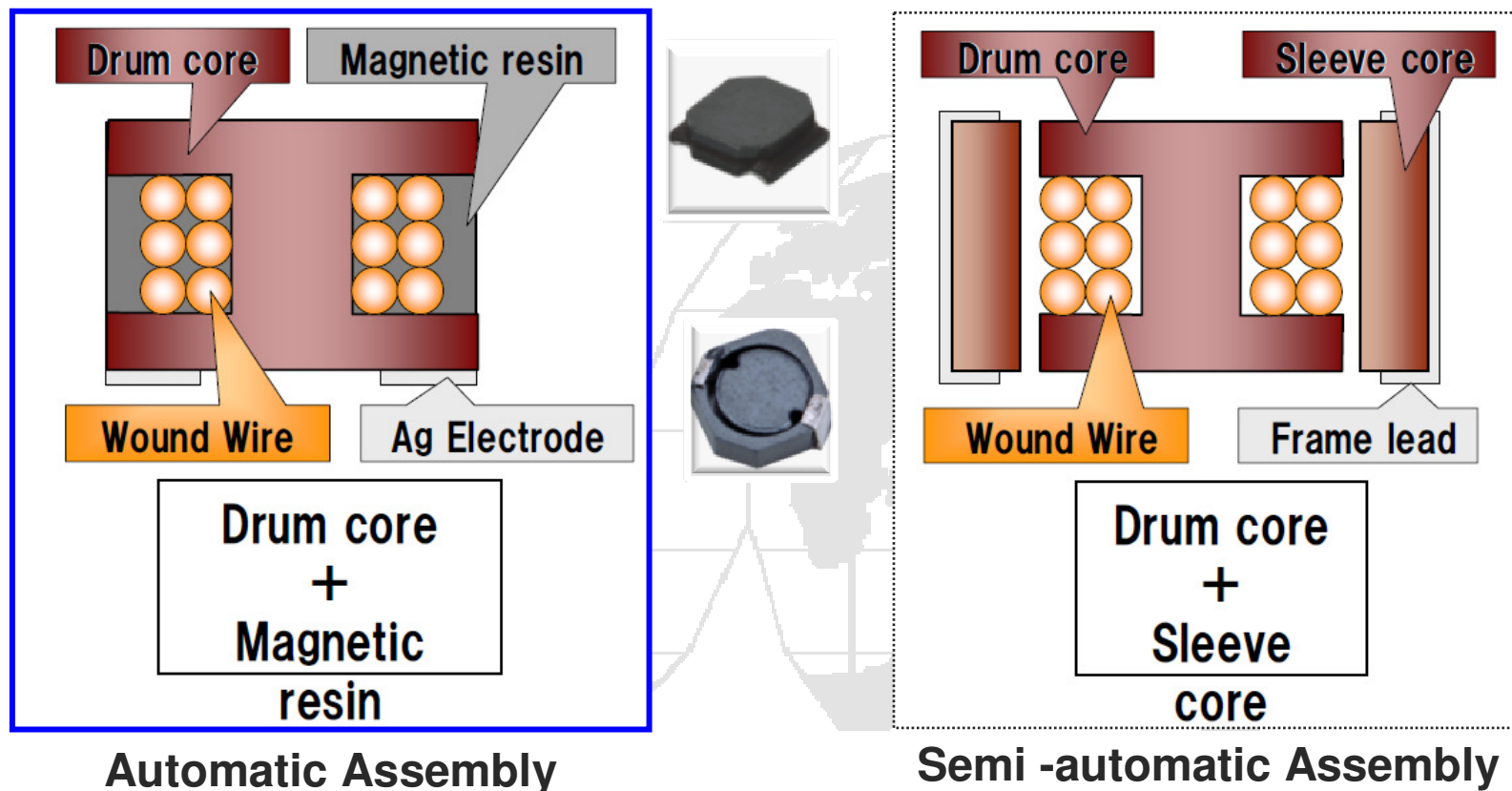
Conventional Manual Process



Fully Automatic Power Inductor Mass Production System



Magnetic Resin



Automatic Assembly

Semi-automatic Assembly

- Coil for DC/DC converters
- Ferrite resin carries out the role of the ferrite sleeve core and bring the cost reduction benefit.
- Large output of automatic assembly
- Sufficient dimensions range from 80*80*40(mm) to low profile 20*16*10(mm).
- Corresponds to high current, though it is the low profile and small.
- Achieved low Rdc and magnetically shielded construction by adopting the magnetic coat resin.

Advantages of LVS

	SCDS104R 4R7	LVS808040 4R7
Dimension (mm)	10*10*4	8.0*8.0*4
DCR (mOhm)	20	18
Irms (A)	5.5	5.5

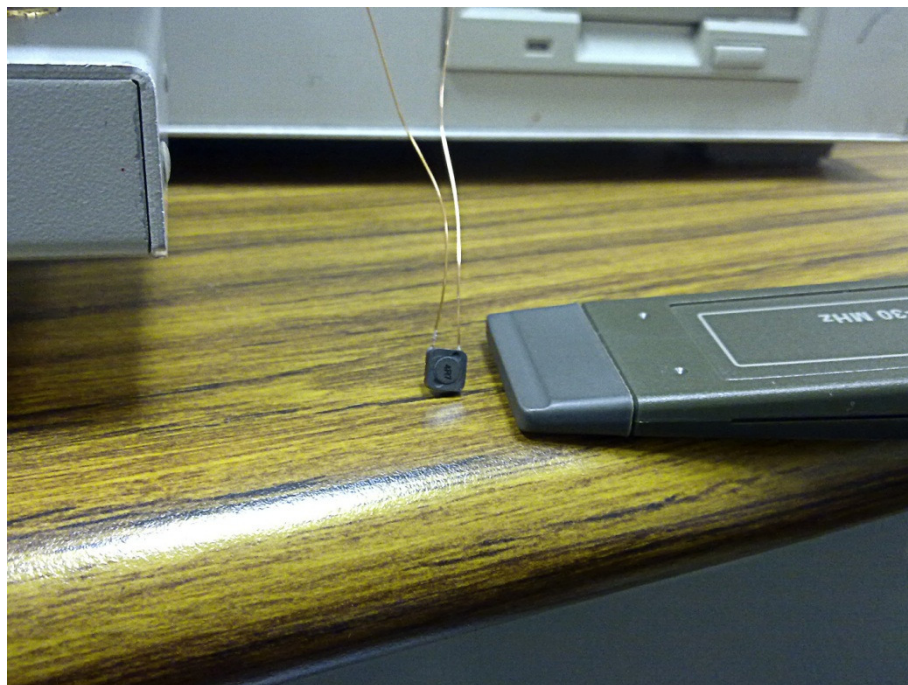
- ◆ **Better Characteristics than RI-Core Based Power Inductor**
- ◆ **Saving the cost for Lead-frame and RI Cores**
- ◆ **Fully Automatic Process for Mass Production**
- ◆ **No Noise issue as Conventional Power Inductor**
- ◆ **No Wire damaged Issue**





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Set-up for SCDS/LVS EMI Comparisons



Source: 5MHz 0.1V



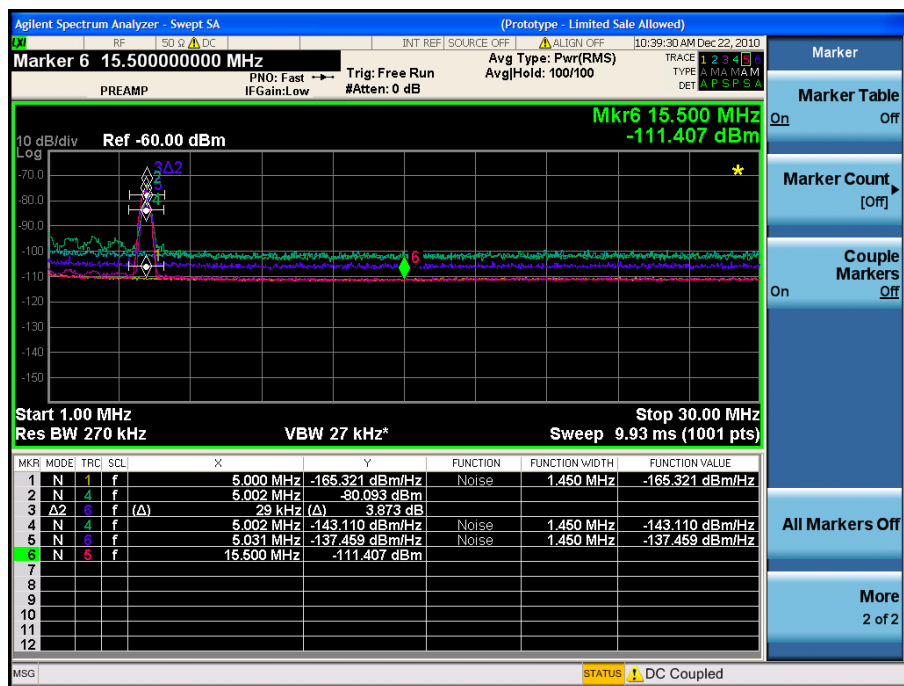
Source: 5MHz 0.1V

Part #	SCDS62T 4R7	LVS606020 4R7
Dimension (mm)	6.2x6.2x3.0	6.0x6.0x2
DCR (mOhm)	80	65
Irms (A)	1.63	2.20

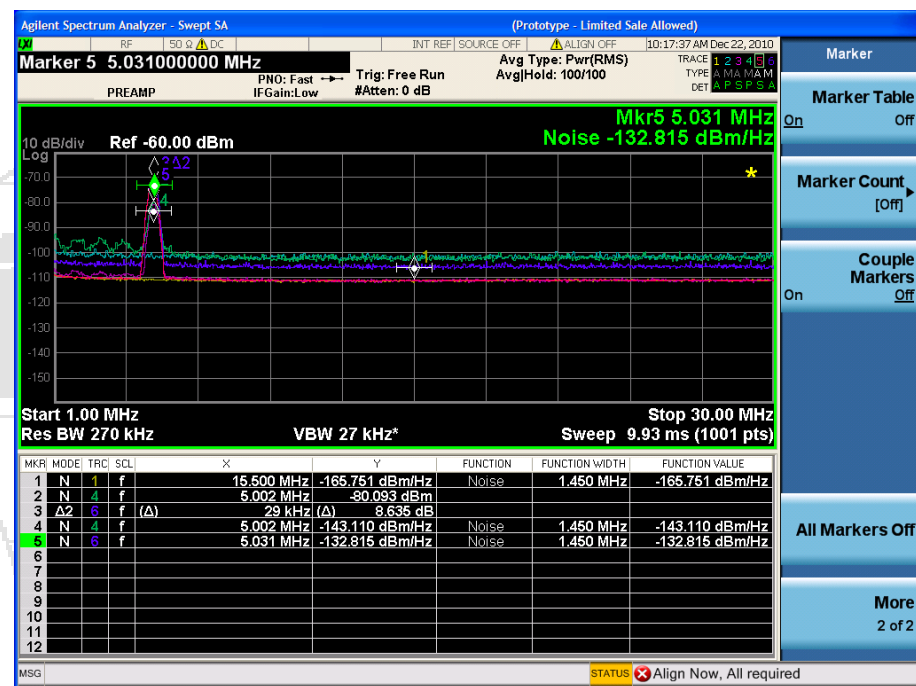


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EMI Comparisons



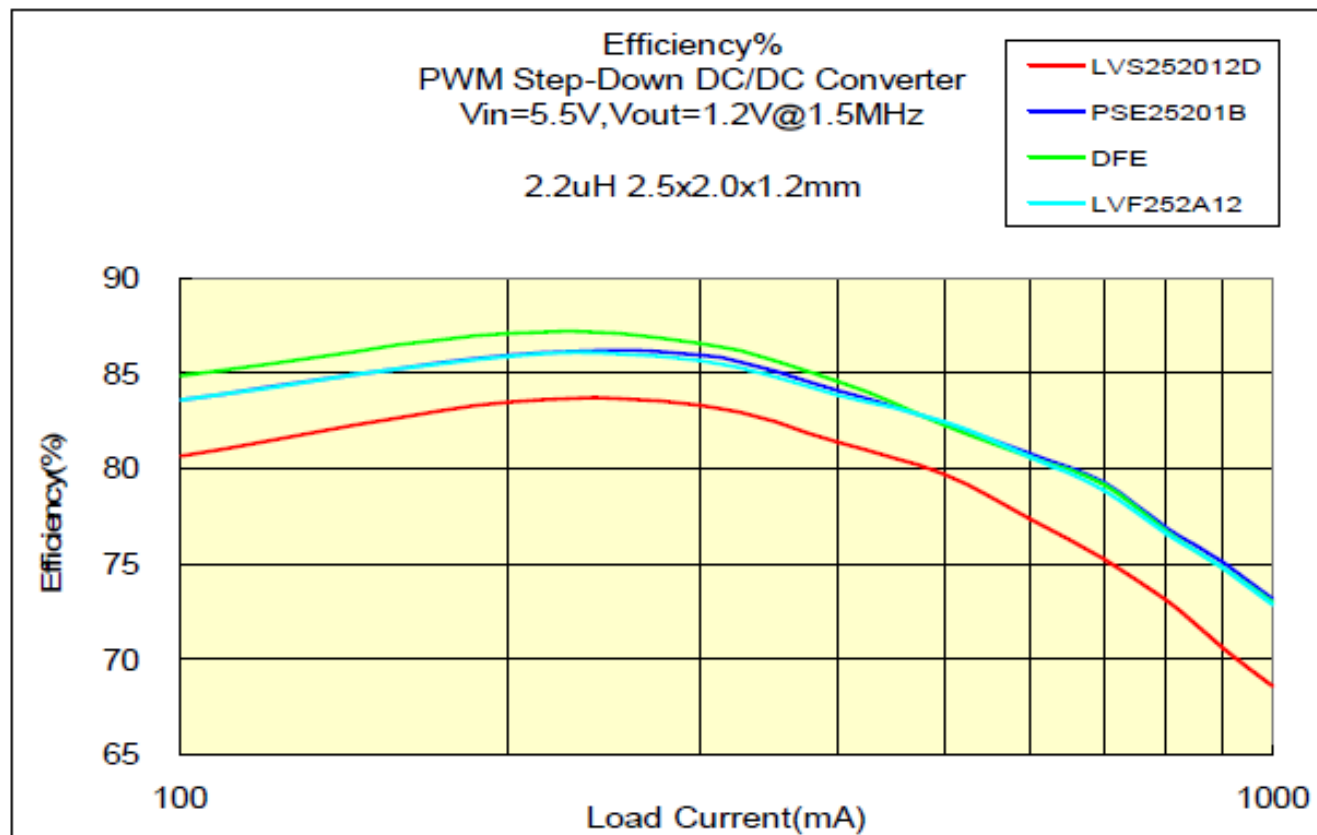
LVS606020 4R7



SCDS62T 4R7

Parts #	LVS606020 4R7	SCDS62T 4R7
EMI Emission	3.873dB	8.635dB

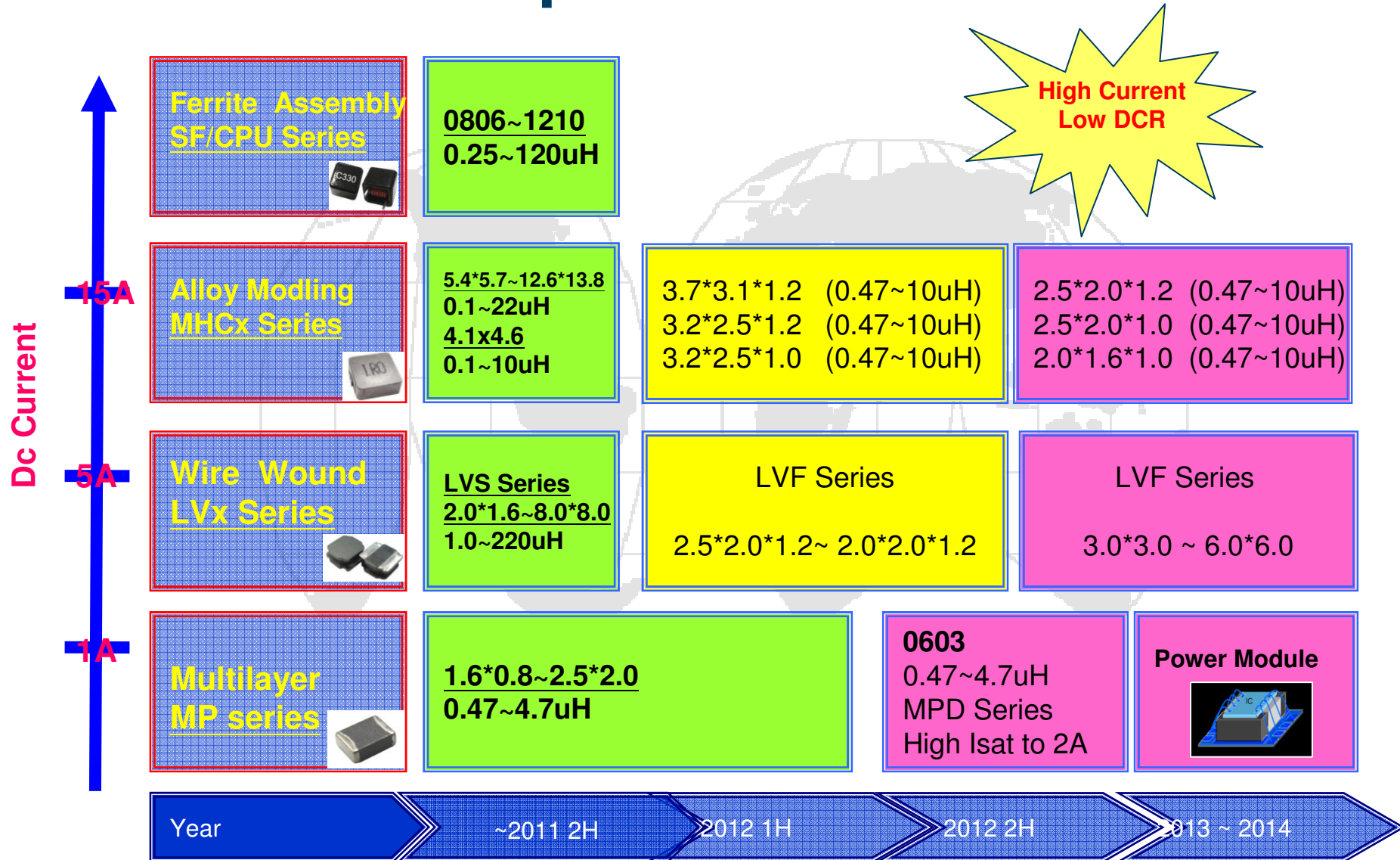
LVS Enhanced - LVF



Series	Inductance	RDC	Isat	Irms
LVS252012	2.2 uH	219 mOhm	1.8A	1.7A
LVF252A12	2.2 uH	80 mOhm	1.8A	1.8A

- ◆ Improved power loss
- ◆ Significant DCR reduction

Roadmap of Power Inductors





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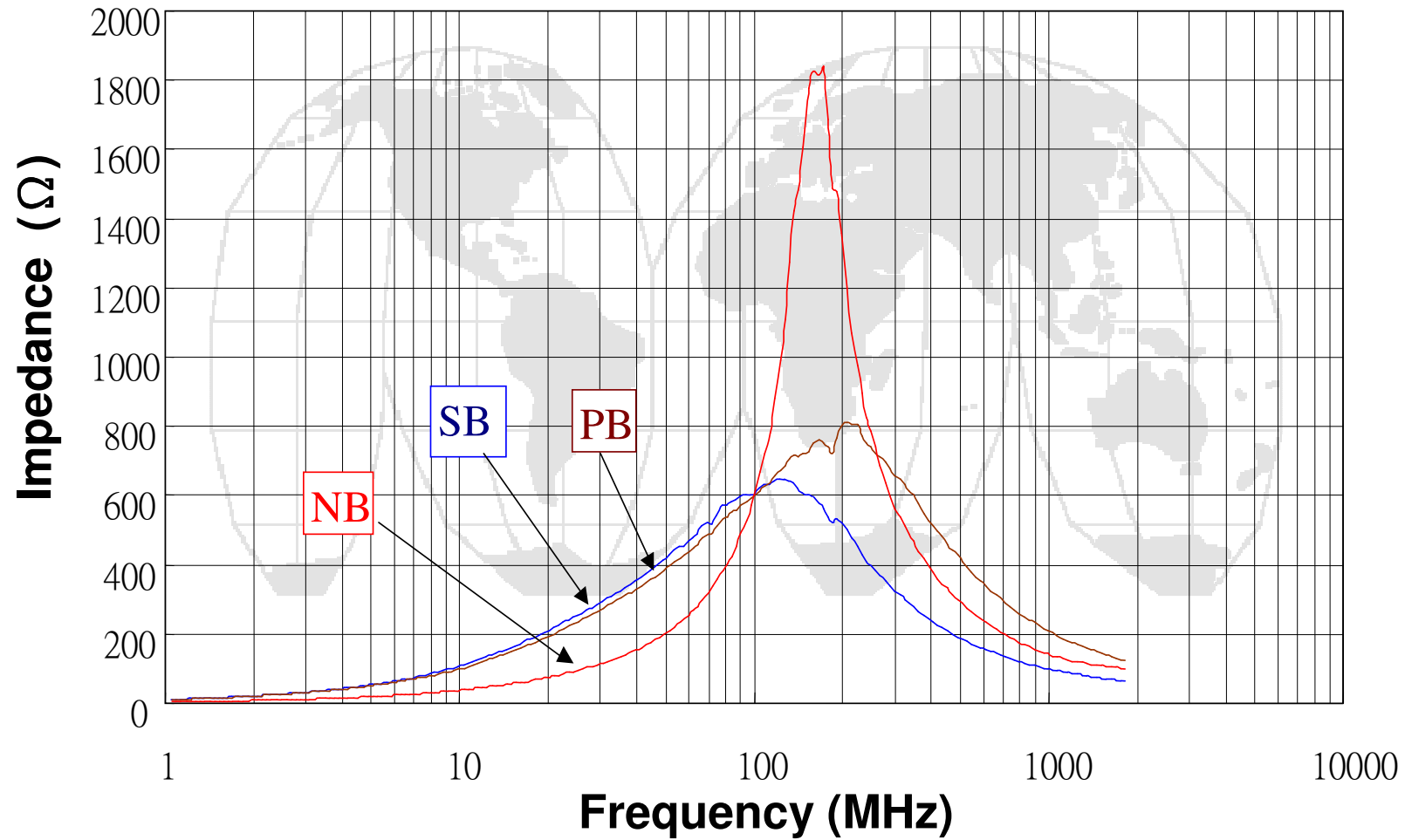


Chilisin Bead Series

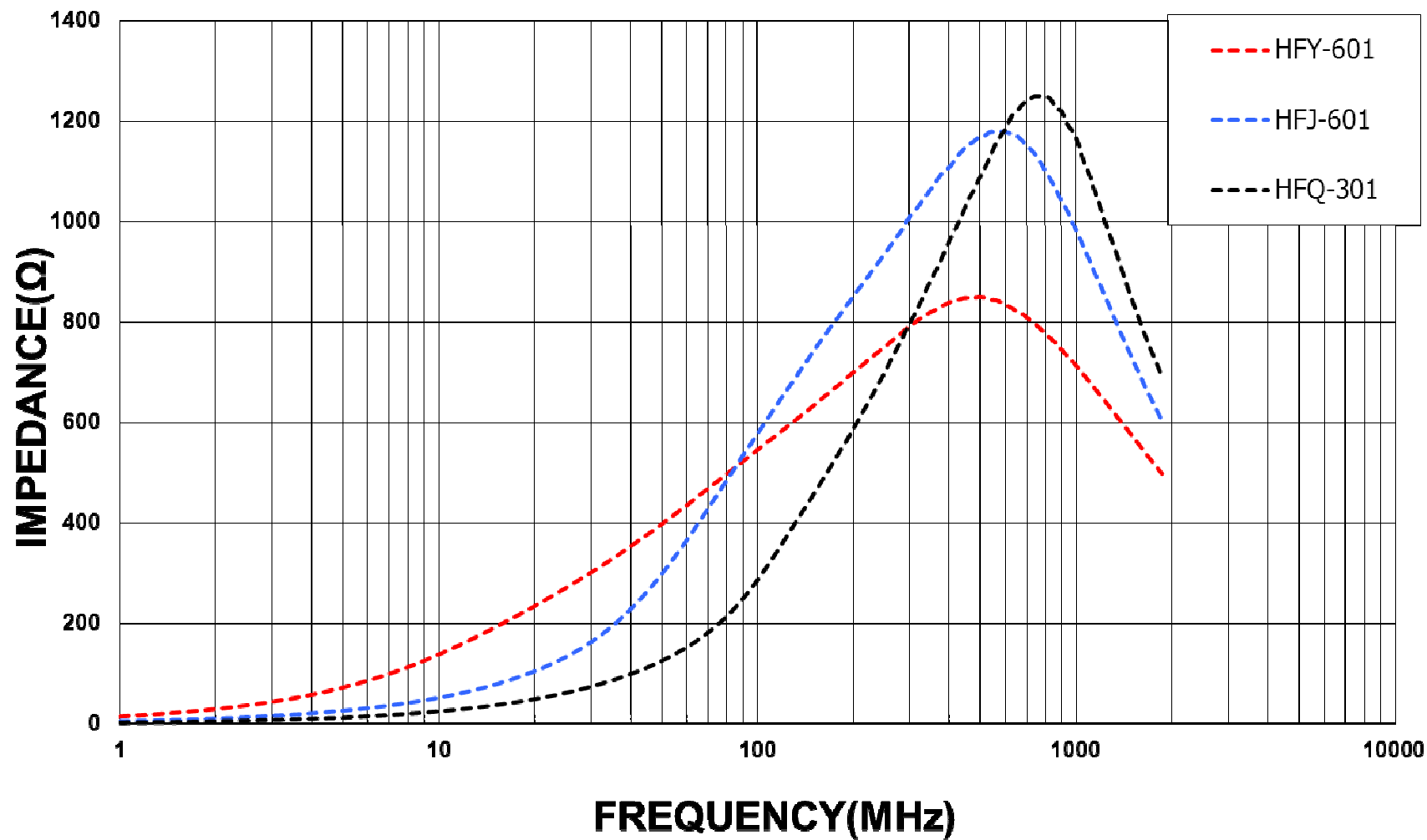
Series	Spec.	Description	Specifications
SB		General Purpose	I: 50-500mA Z: 5 – 2.7K Ω
GB		General Purpose	I: 100-1000mA Z: 7 – 2K Ω
NB		Digital signal	I: 50-500mA Z: 3 – 2.7K Ω
PB		High Current	I: 800-6000mA Z: 5 - 1.5K Ω
UPB		Ultra High Current	I: 4000-6000mA Z: 10 – 330 Ω
HF/HP		Giga Band >GHz	I: 50-2000mA Z: 120 – 1.8K Ω

Different In-house Powder to Design and Modify Performance of Beads

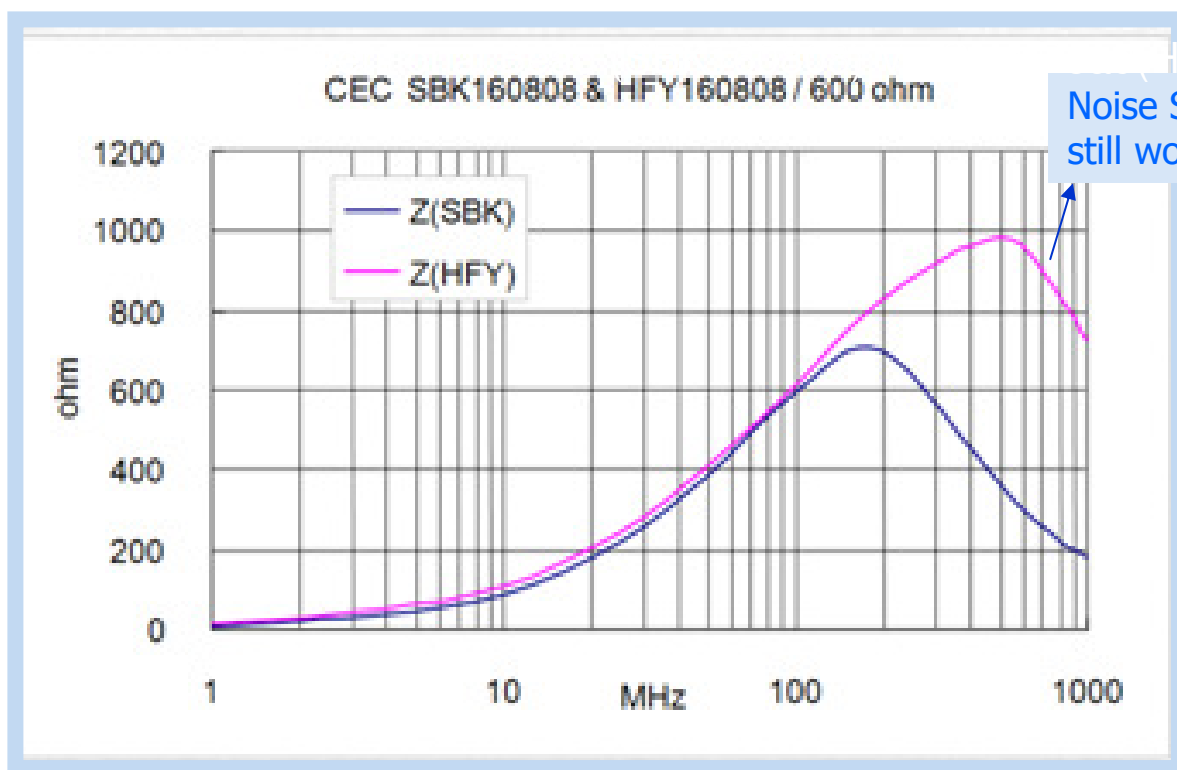
Bead Characteristics < 1GHz



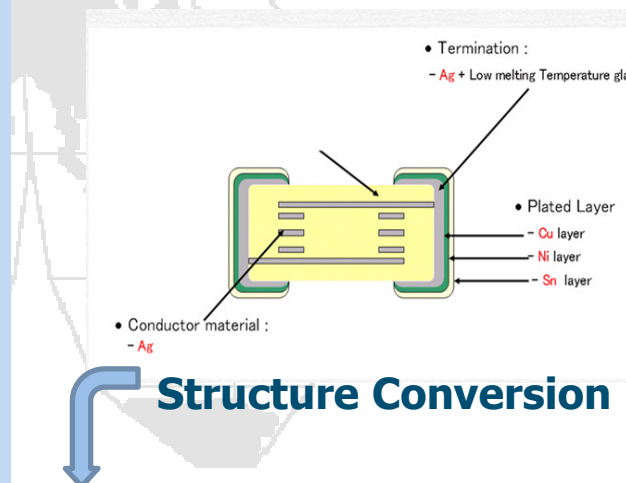
Bead Characteristics > 1GHz



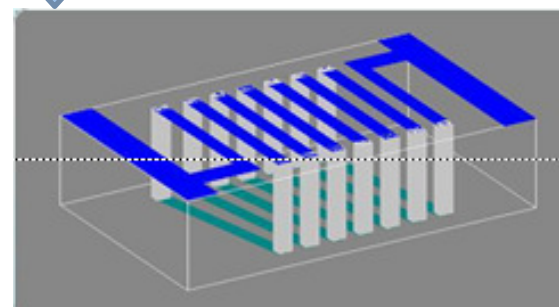
GHz Chip Bead



Noise Suppression
still working at GHZ band

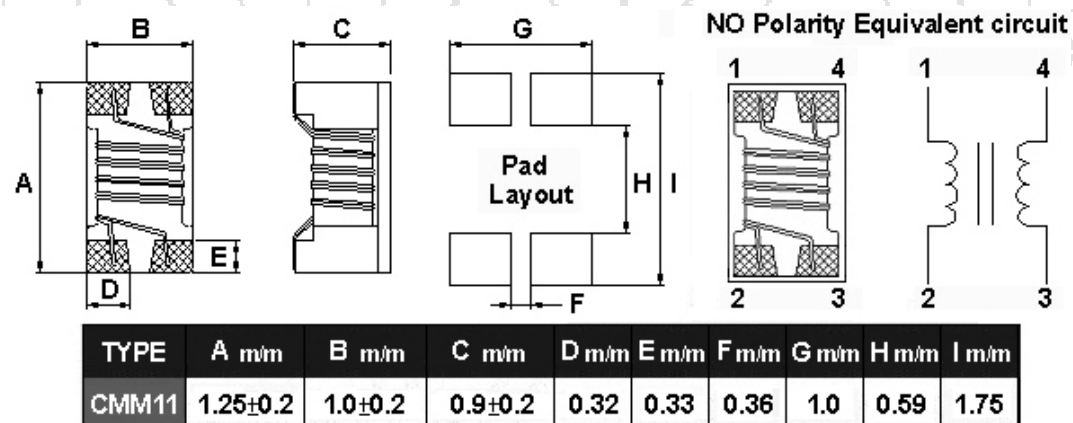


Structure Conversion

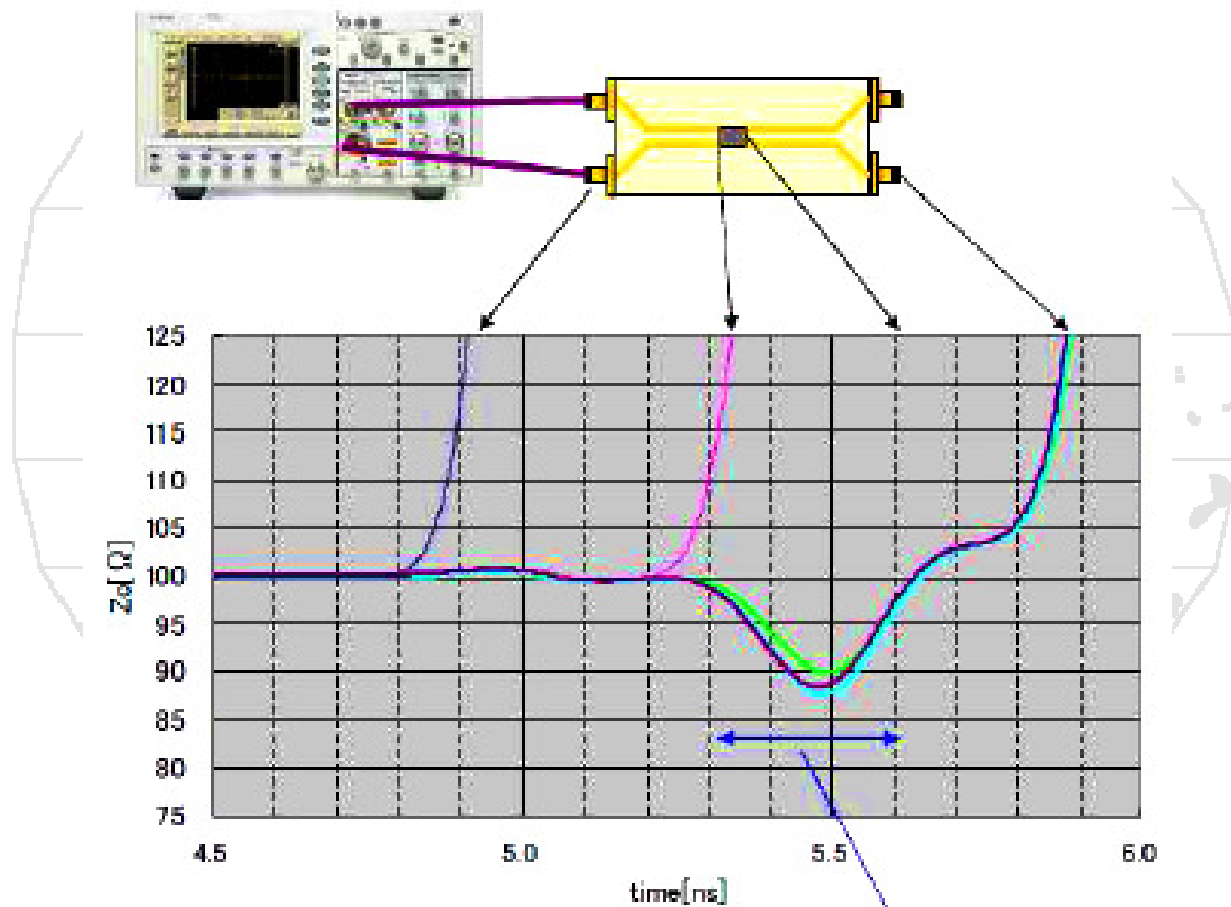


Chilisin Common Mode Choke

Series \ Spec.	Application	Specifications
CMM11	USB 3.0 5 G bit/s	I: ~300mA Z: 60 – 160Ω
CMHD21	HDMI 3 G bit/s	I: ~400mA Z: 67 – 120Ω
CMM21	USB2.0 480 M bit/s	I: ~450mA Z: 30 – 900Ω



TDR Measurement on HDMI CMM



Above the Limits of 85 Ω



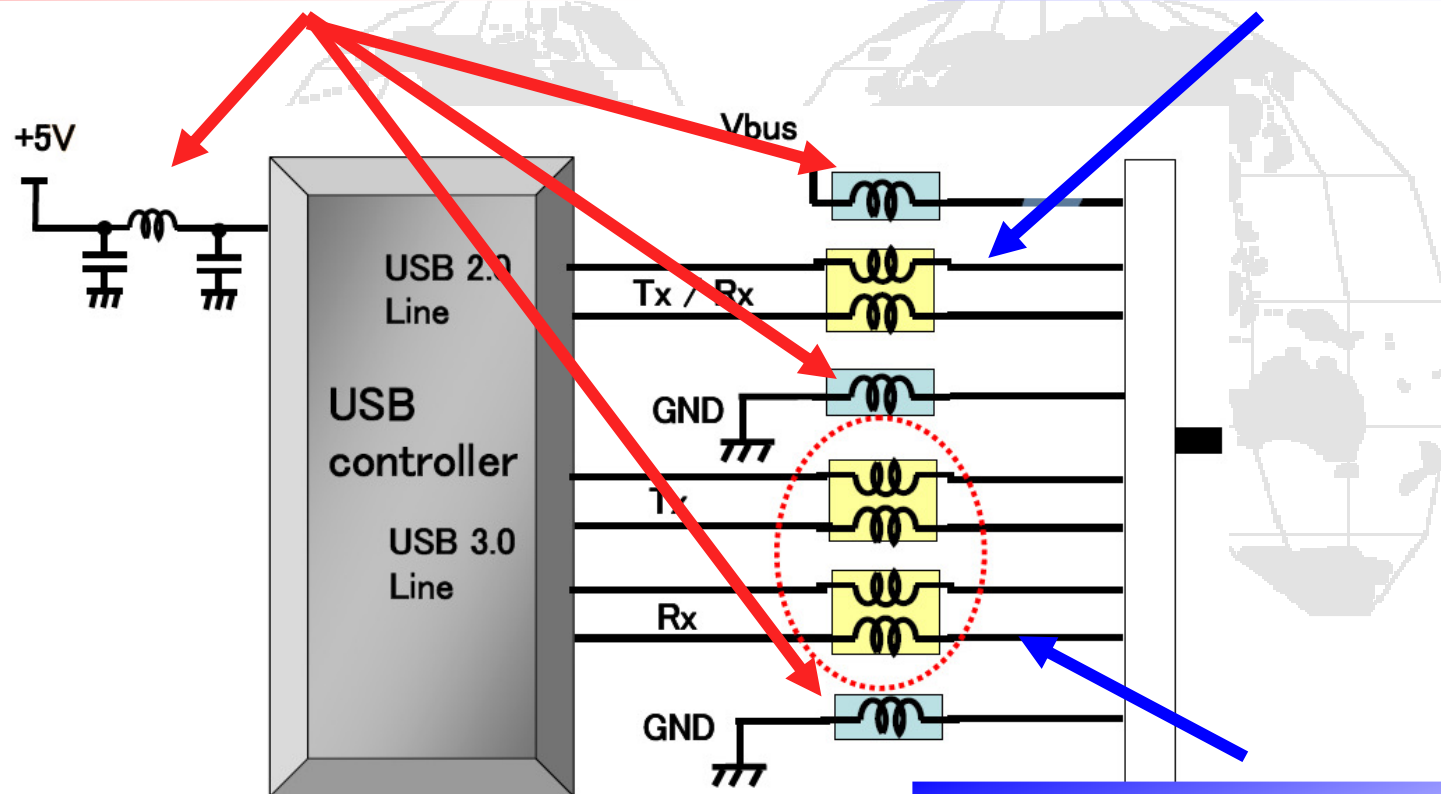
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USB 3.0

Chip ferrite beads

Common mode choke coil:

CMM21T-900M
CMM11T-900M

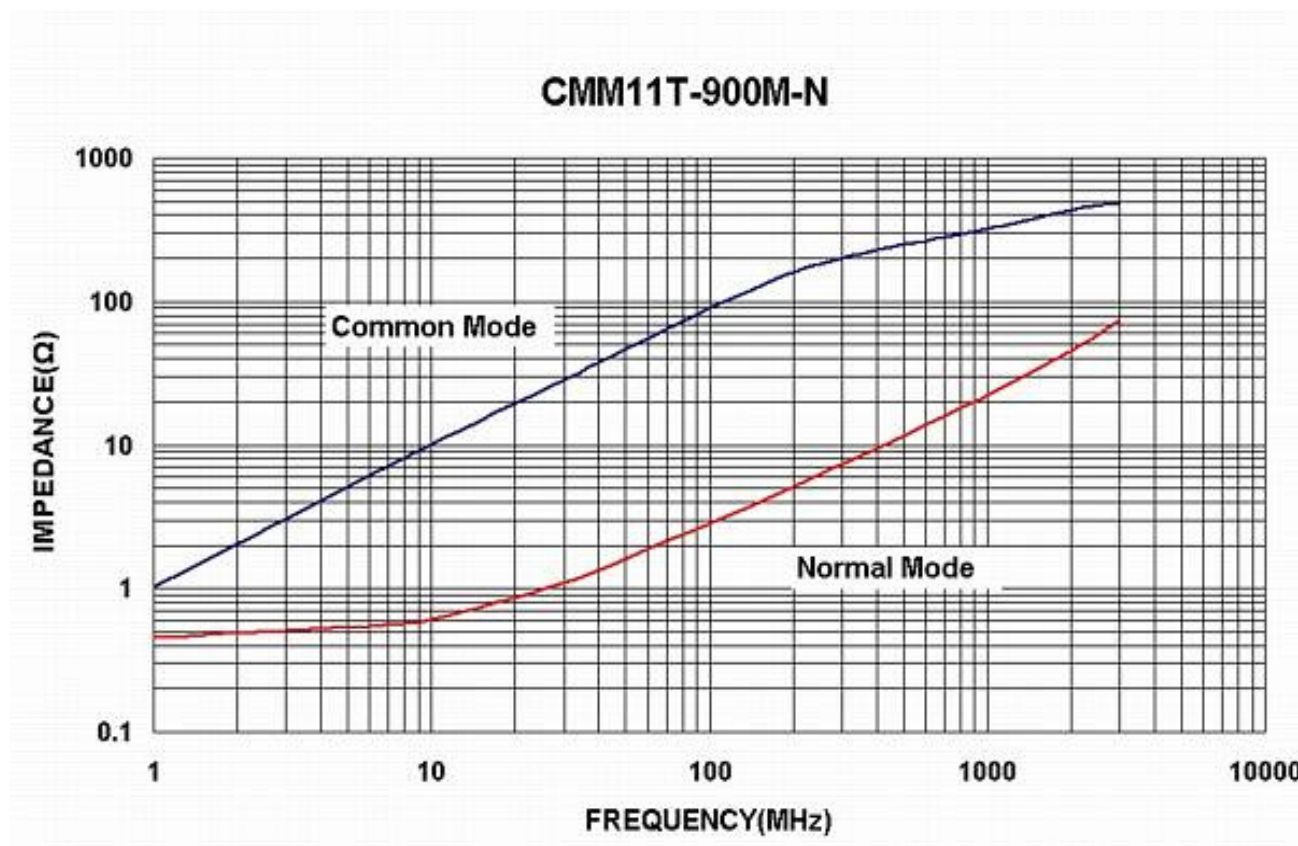


Common mode choke coil:

CMHD21T-670M
CMM11T-670M



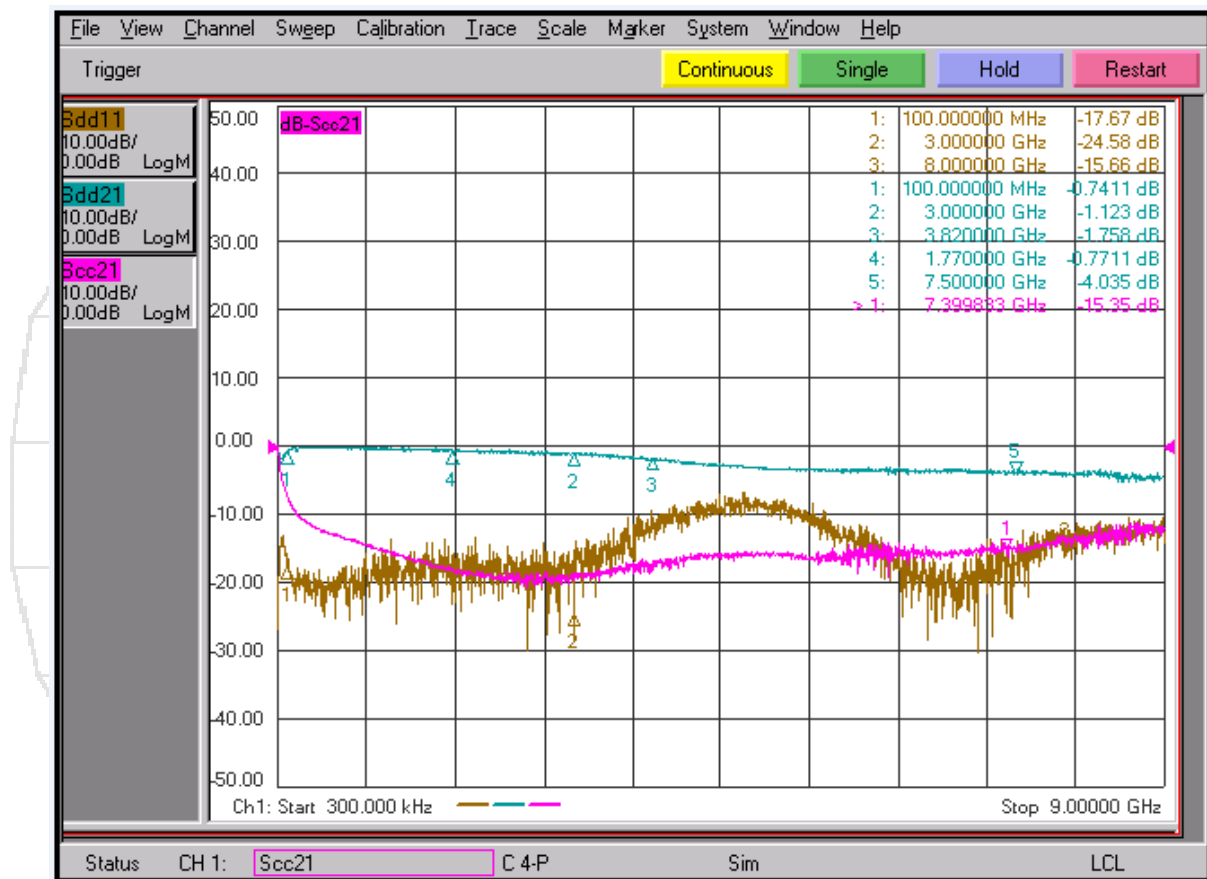
Common Mode Choke Performance





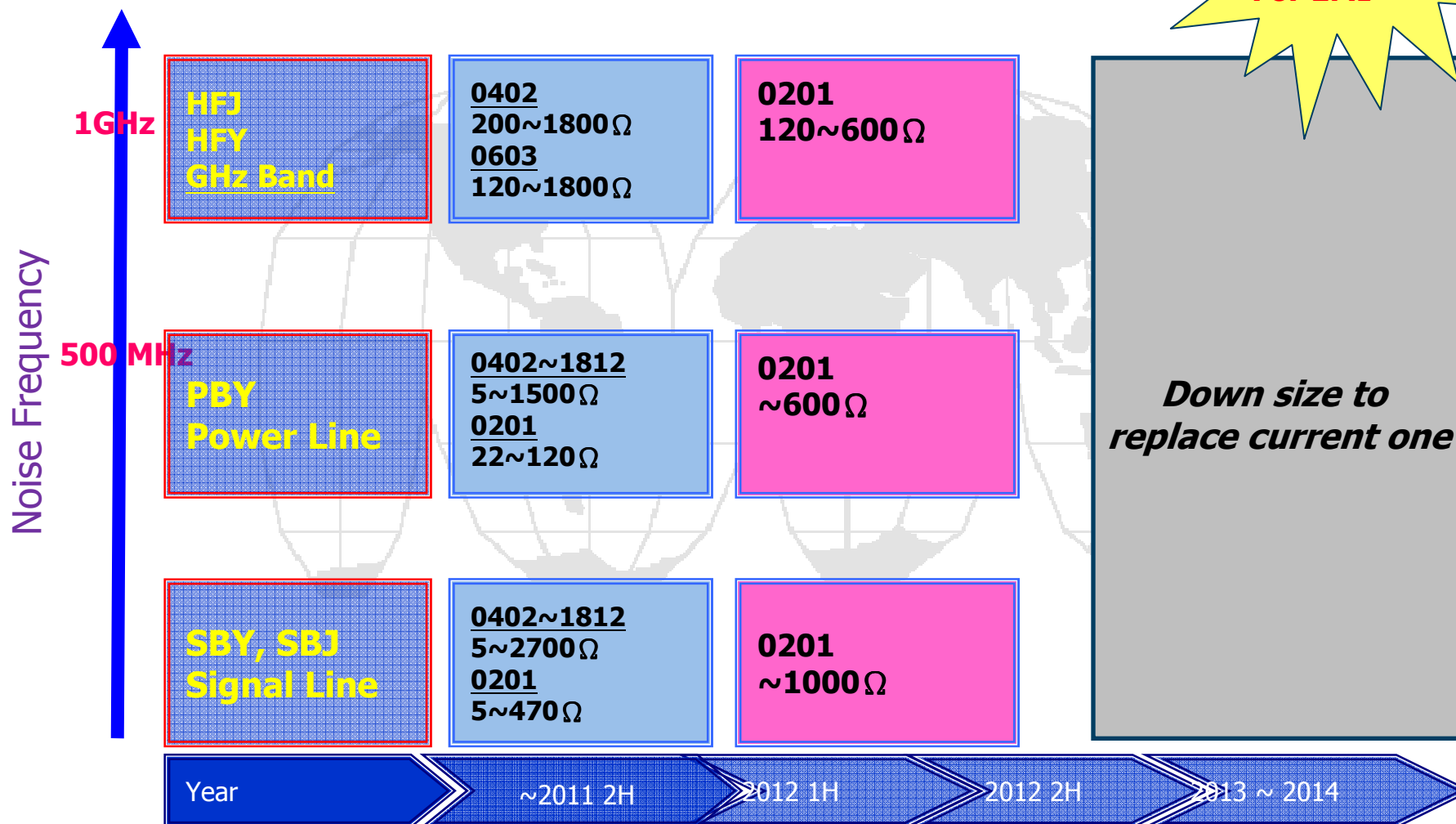
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CMHD21T-750M Insertion loss



Insertion Loss	2.5GHz, -1.7dB	5.0GHz, -3.5dB	7.5GHz, -5dB
CMHD21T-670M	-1.7dB	-3.32dB	-4.23dB

Roadmap of Chip Bead





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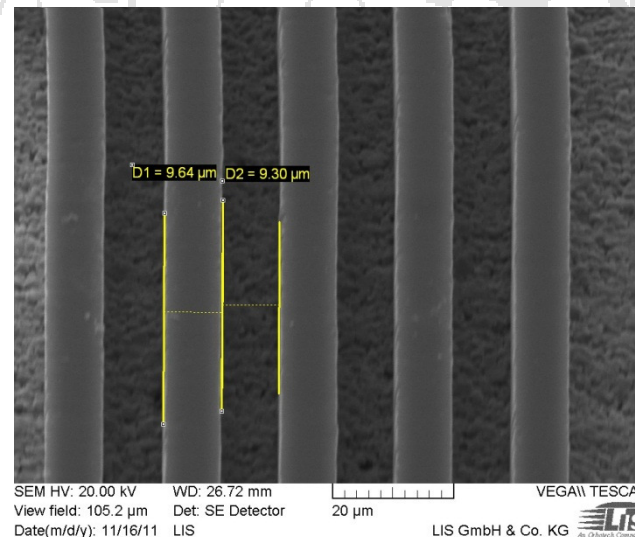
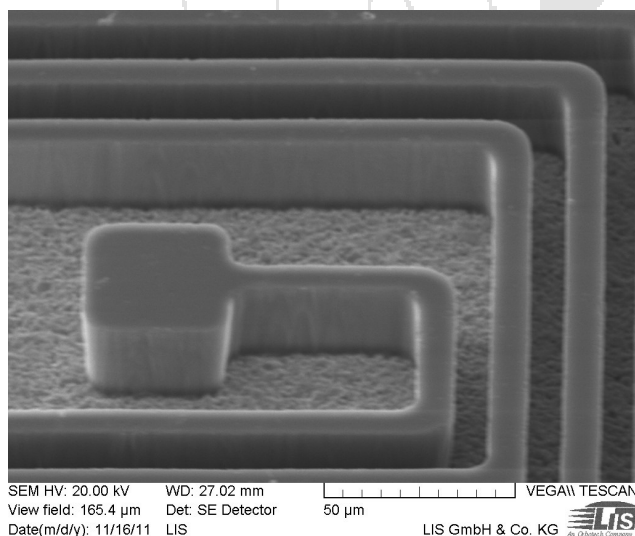
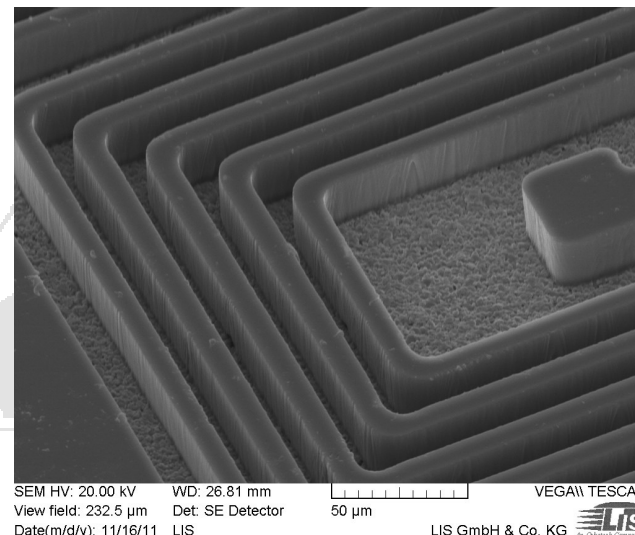
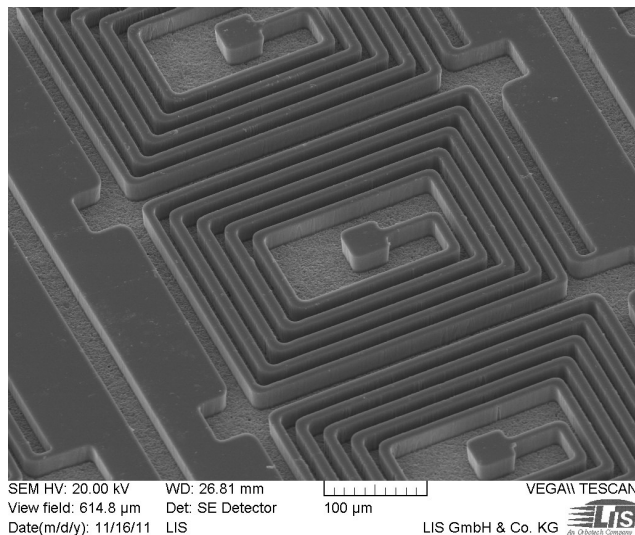
Hi-Freq Chip Inductors

Series	Spec.	Structure	Specifications
CLH		Multilayer	Miniature: 0.6 x 0.3 x 0.3 Q up to 20 SRF up to 10GHz
CS		Wirewound	Q up to 80 SRF up to 12GHz
CM		Wirewound	Q up to 40 SRF up to 18GHz
TFL		Thin Film	Miniature: 0.6 x 0.3 x 0.25 Q >12 SRF up to 6GHz



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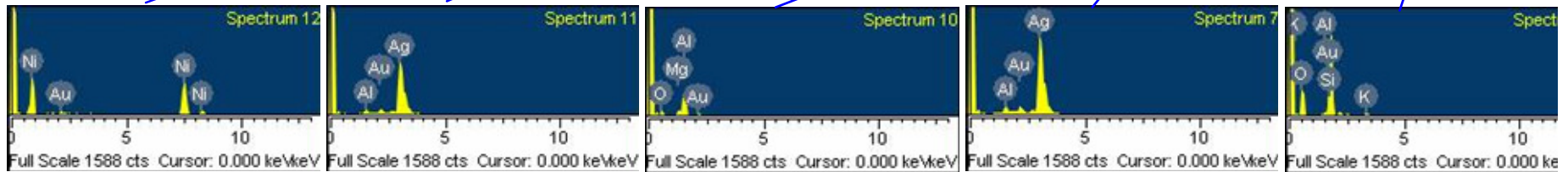
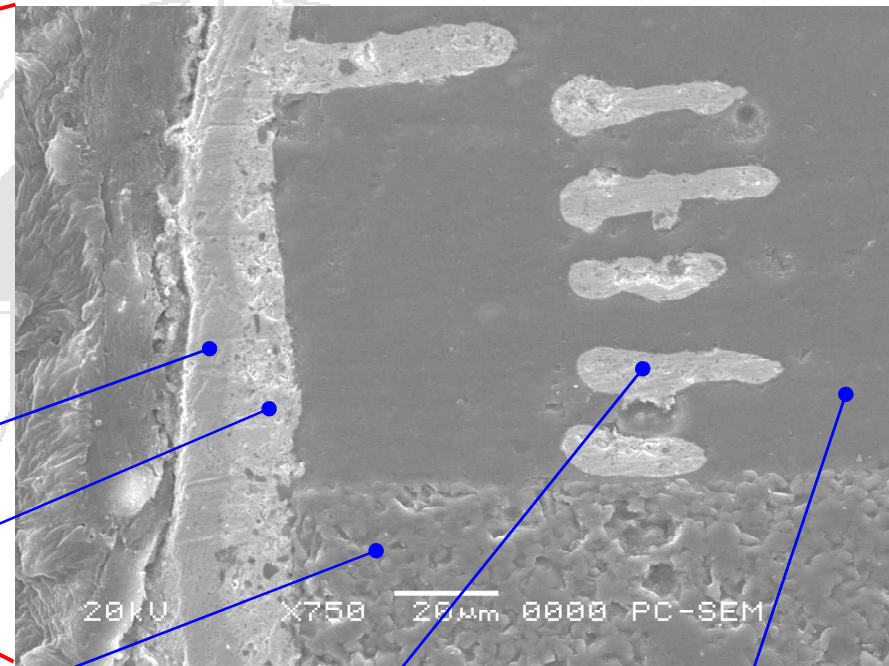
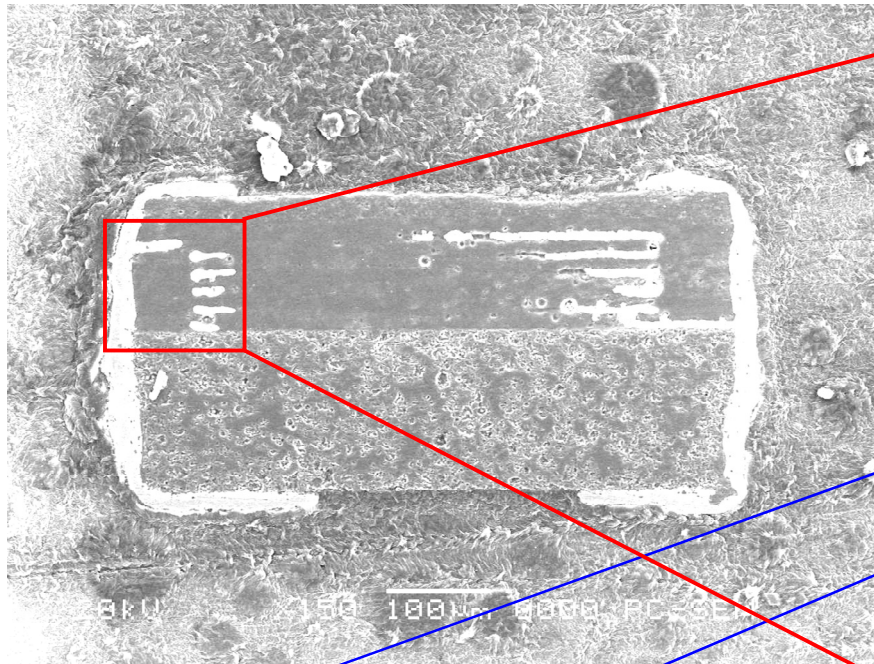
Thin Film Inductor Process





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Thin Film Inductor Process

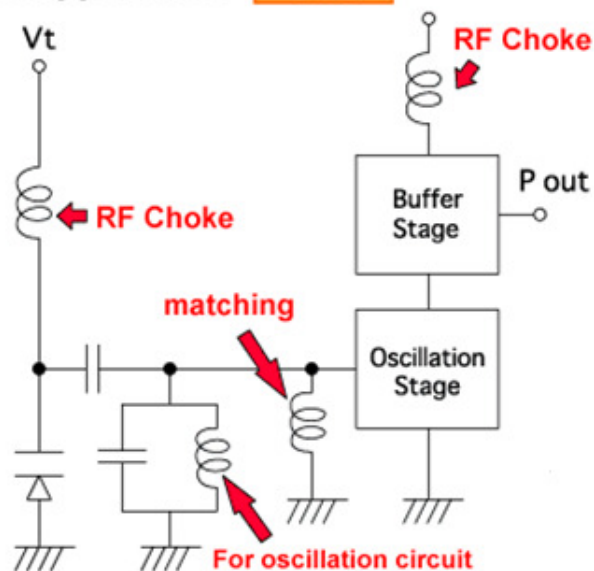


Multilayer VS Thin Film

P/N	Inductance (nH)	Q	SRF (GHz)	DCR(ohm)	IDC(mA)	Tolerance
CLH0603T-3N3S-S	3.3	4	9.2	0.12	200	±0.3nH
TFL0603T-3N3B-S	3.3	12	6	0.25	450	±0.1nH★

for Application

VCO



Matching coil

The matching coil should be a high-Q type or tight inductance tolerance type coil for stable oscillation and signal quality.

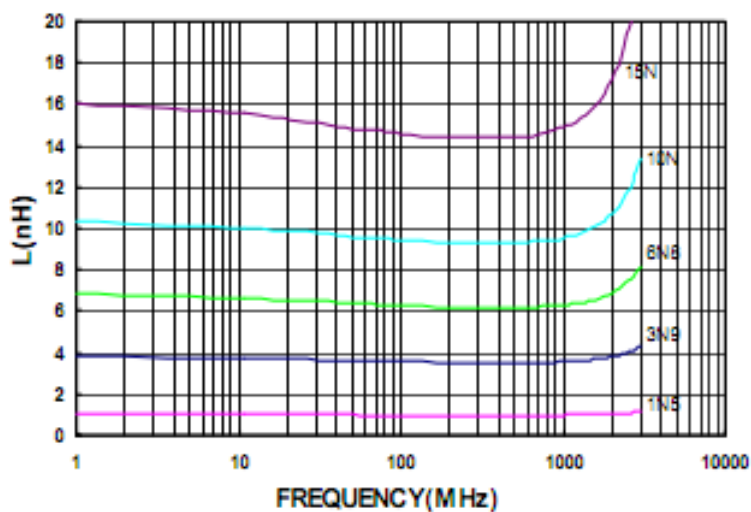
A film type coil is suitable if tight inductance tolerance is required.

* An example of the matching circuit

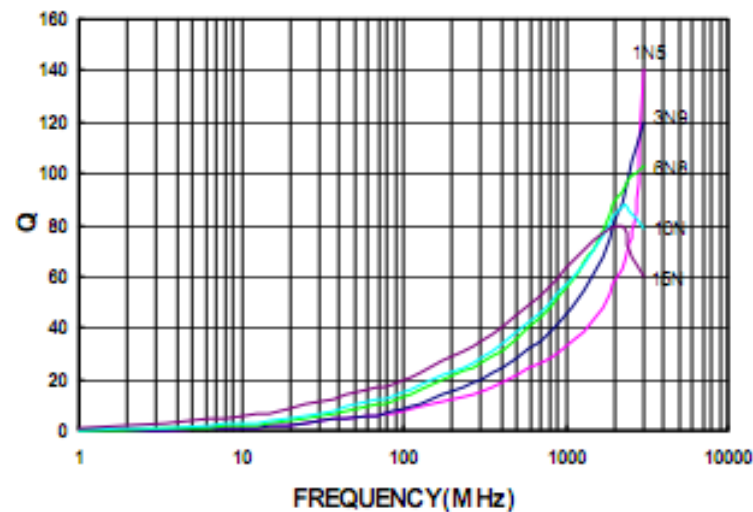
Multilayer VS Wirewound

P/N	Inductance (nH)	Q	SRF (GHz)	DCR(ohm)	IDC(mA)	Tolerance
CLH1005T-3N9S-S	3.9	8	6.3	0.15	400	±0.3nH
CS0402-3N9J-S	3.9	19	7	0.066	840	±5%
★ CM0402-3N3J-S	3.9	25	10	0.07	750	±5%

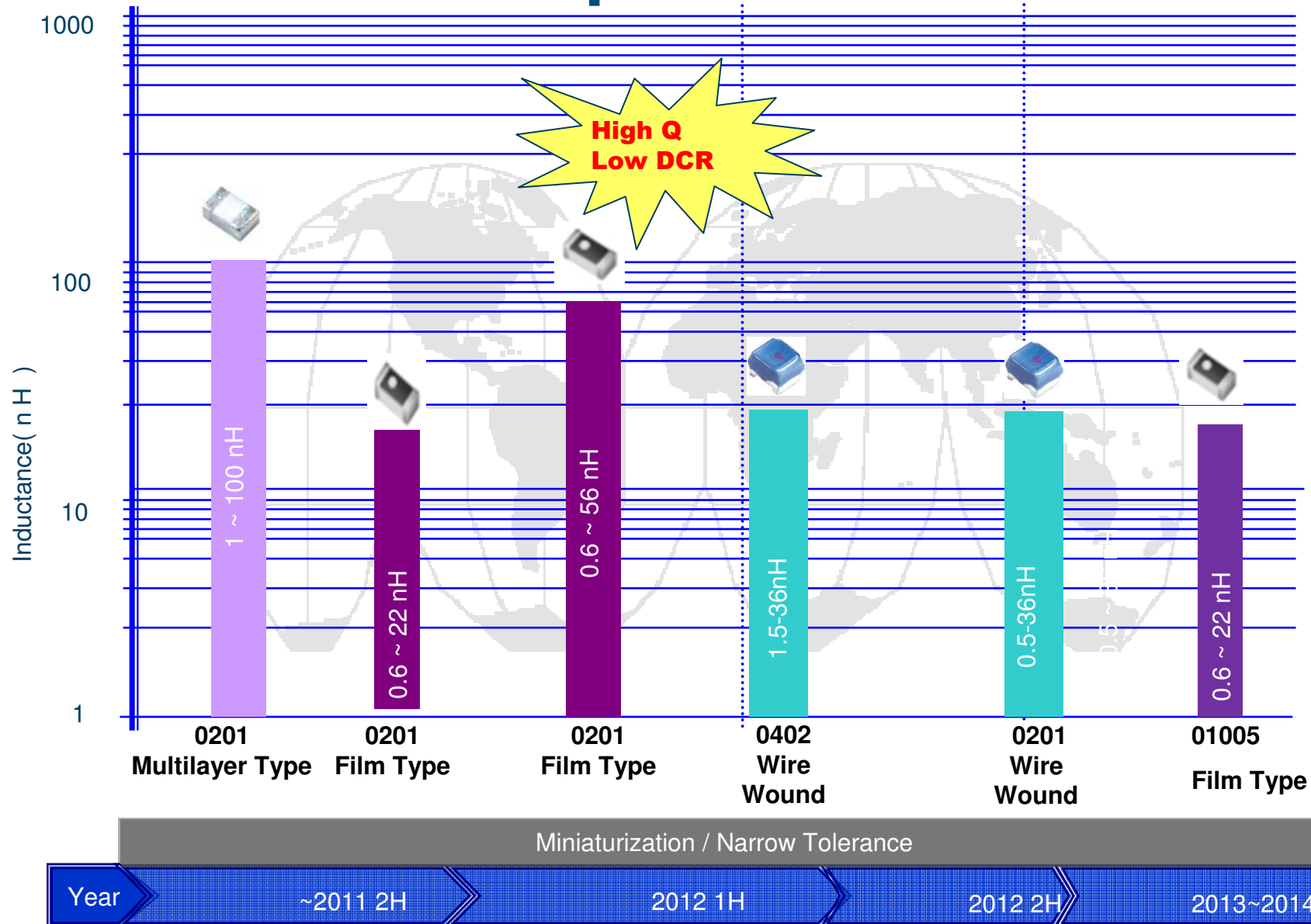
Typical L vs. Frequency



Typical Q vs. Frequency



Road Map of RF Inductors



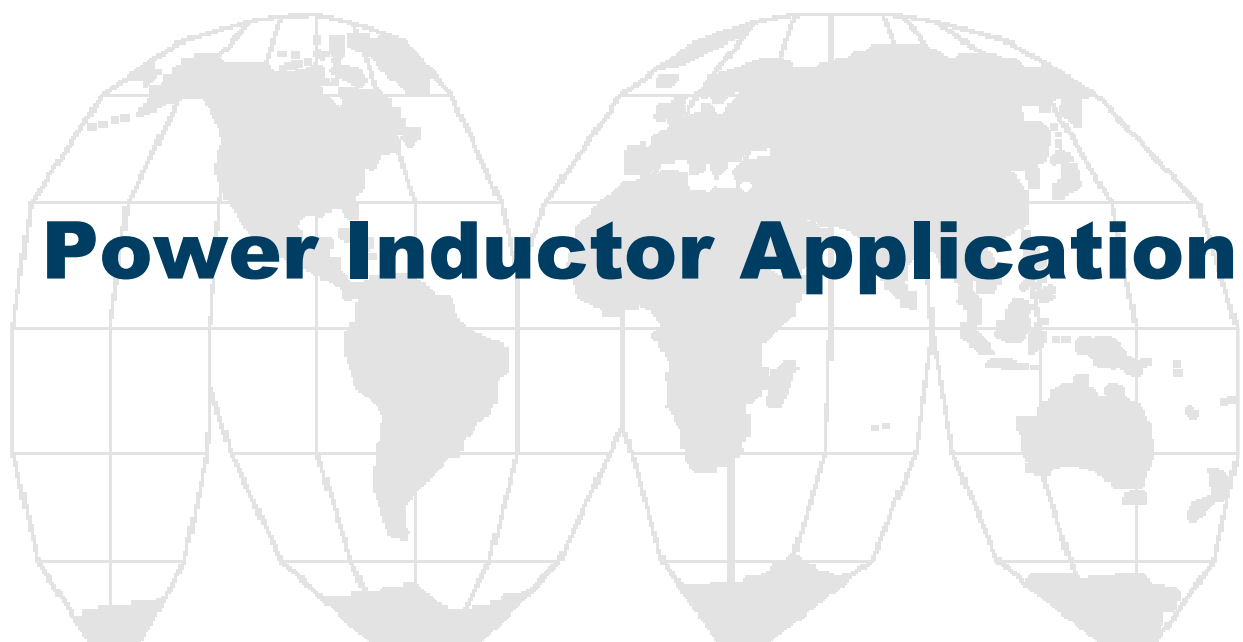


Product Comparison Sheet

Product / Supplier	Chilisin	TDK	Murata	T-Yuden	Vishay	Coilcraft
Multilayer Bead	v	v	v	v	v	
Multilayer Power Inductor	v	v	v	v		
Multilayer Ceramic RF Inductor	v	v	v	v	v	
Wire-wound Ceramic RF Inductor	v		v	v	v	v
Common Mode Choke	v	v	v	v	v	v
Power Inductor	v	v	v	v	v	v
Molding Power Inductor	v	v			v	v

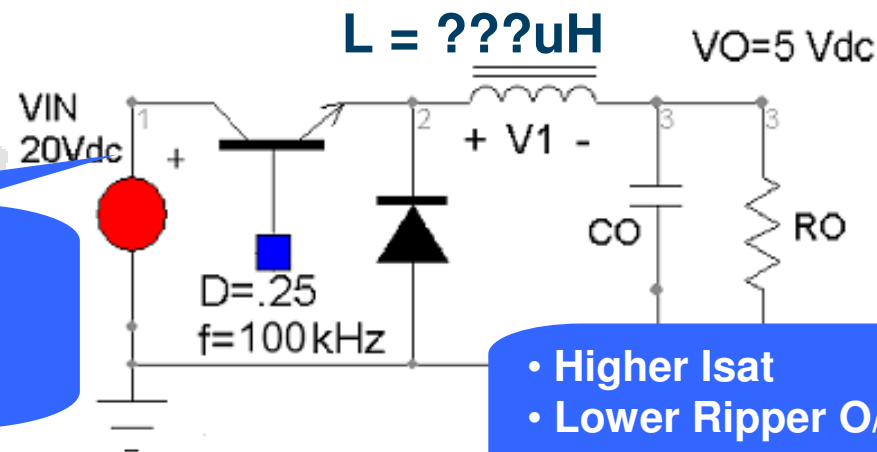


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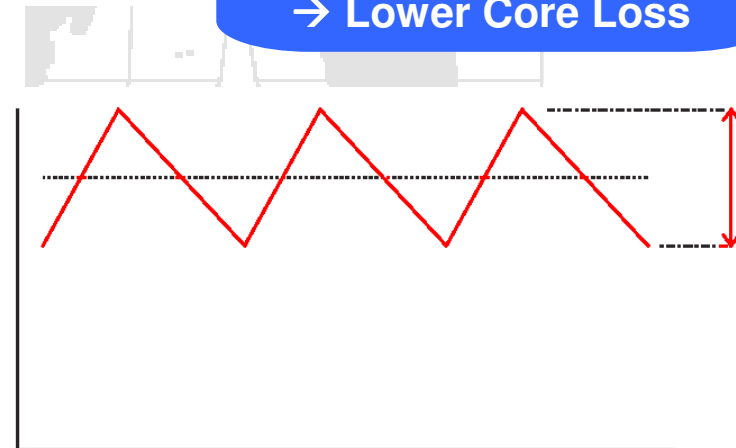
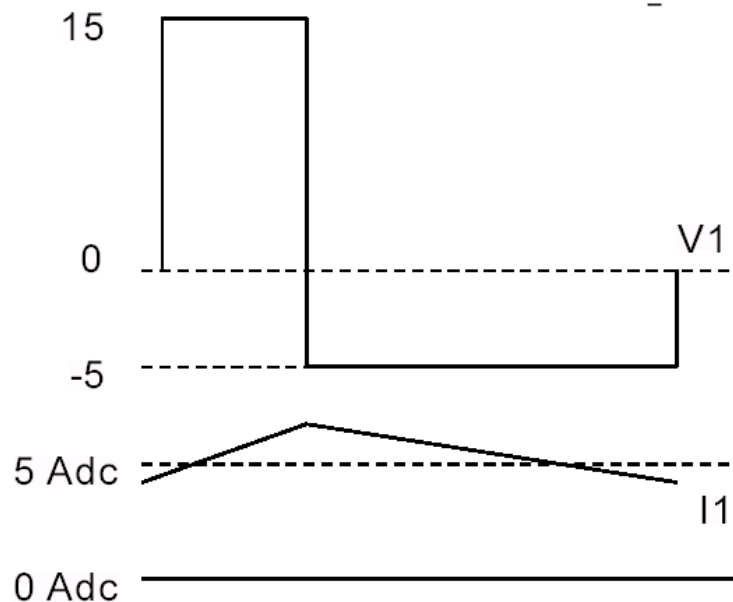


Keys to the DC to DC Applications

- Inductance Determination
- Lower DCR
→ Lower PWR Dissipation
- Higher irms



- Higher Isat
- Lower Rippler O/P
→ Lower Core Loss



DC Choke Design for Buck Converter

Parameters	Specification
Input, V_{in}	12V
Output, V_{out}	5V
Load current	4.5A
Ripple current	20%
Operating frequency	600KHz

L & Temperature Rise = ???

$$(V_{In} - V_{Out}) = L \times \Delta I / \Delta T$$

$$(V_{In} - V_{Out}) = (12 - 5)$$

$$\Delta T = \frac{V_{Out}}{V_{In}} \times Cycle \ time$$

$$= \frac{5}{12} \times 1 / 600K$$

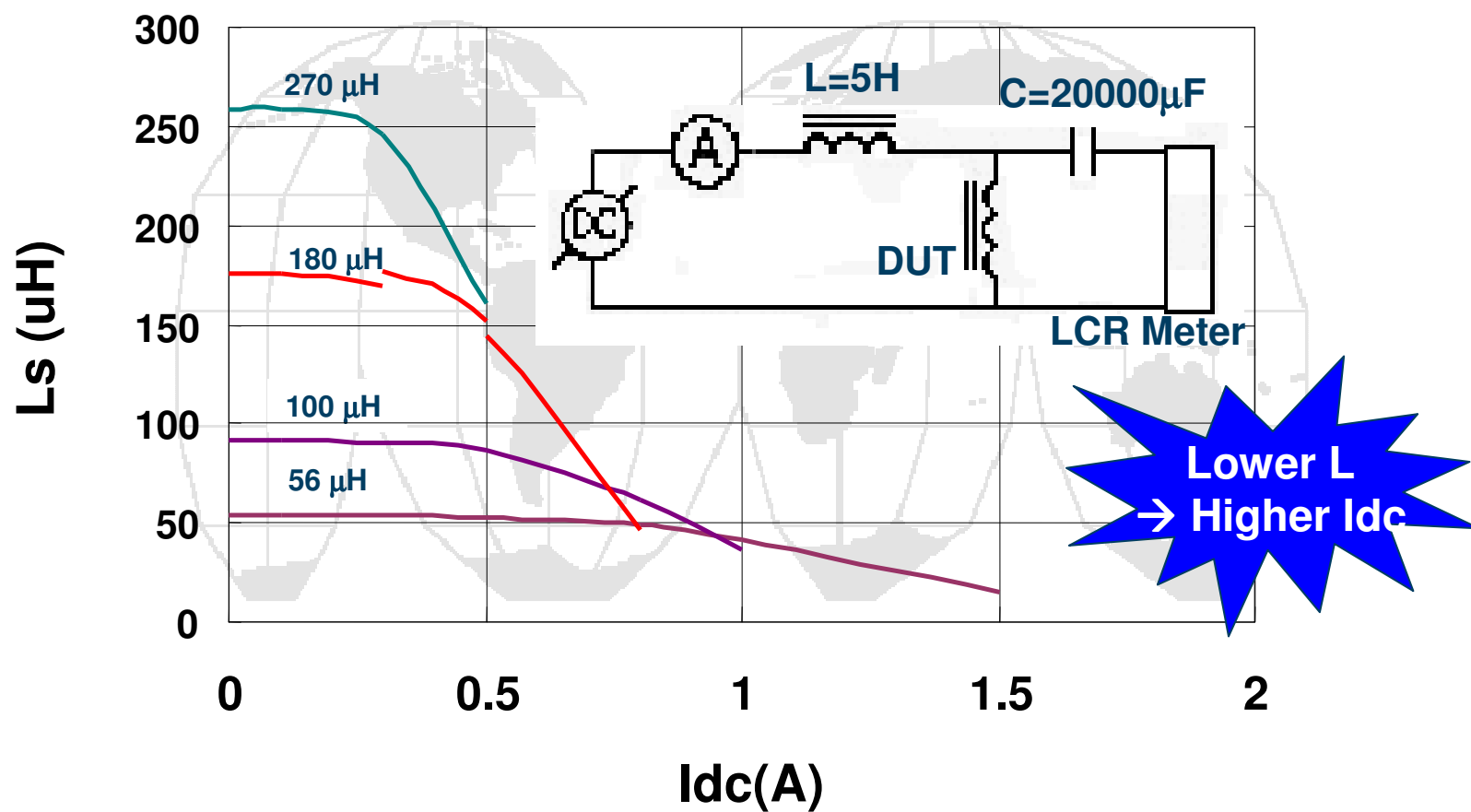
$$\Delta I = 4.5A \times 20\%$$

$$L = (V_{In} - V_{Out}) \div \Delta I / \Delta T$$

$$= (12 - 5) \div \frac{(4.5 \times 0.2)}{(\frac{5}{12} \times 1 / 600K)}$$

$$= 5.4\mu H \Rightarrow 5.6\mu H \rightarrow 19.3\% \text{ Ripple}$$

Idc Measurement





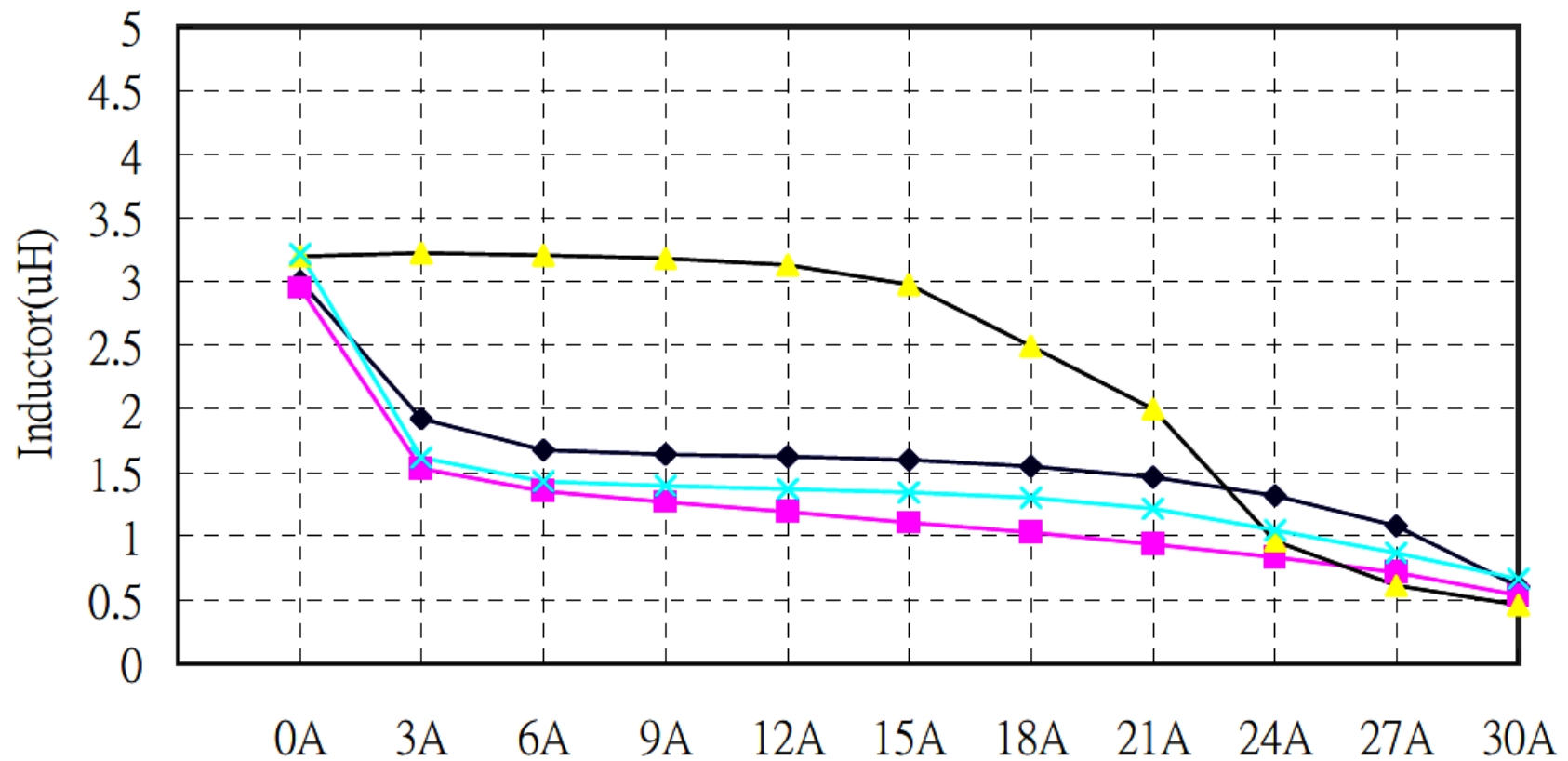
Saturated & Rated Current, I_{dc}/I_{rms}

I_{dc} : 10% drop in Inductance under DC bias
: Same as I_{sat}
: Dynamic or transient measurement

I_{rms} : body temperature increasing in $\Delta T < 40^{\circ}\text{C}$
under rated current for 2Hrs.

SCDS 127 1R0	CEC (-10%)	Sumida (-70%)
I_{dc}	5.4 A	14 A

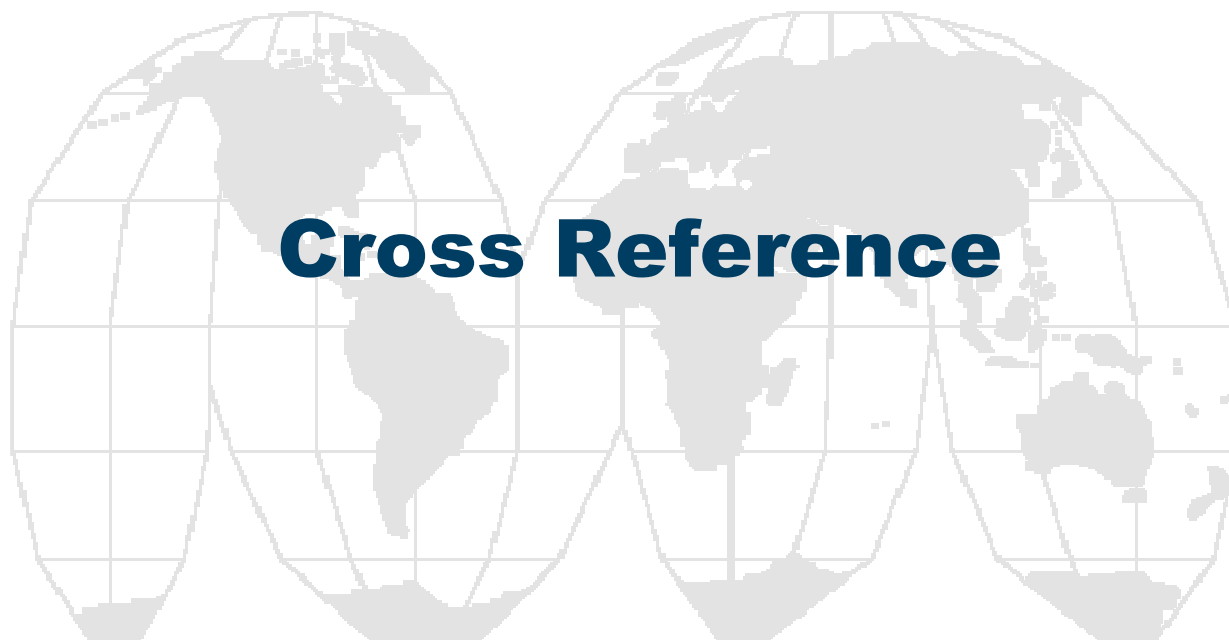
Designing the Desired Inductance with Loading





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Total Solution Provider for EMI, Power and RF.



Multilayer Chip Beads

Multilayer	Category		Chilisin	Murata	TDK	Taiyoyuden	NIC
Chip Beads	For Digital Interface		SBR	BLMxxRK	MMZxxxxR		
	General Signal	Standard	SBY/SBK	BLMxxAG	MMZxxxxS	BKxxxxHS/H M	
		Low DC Resistance	GBY/GBK	BLMxxAG			
	For High Speed Signal (Sharp impedance)		SBJ	BLMxxBD	MMZxxxxY	BKxxxxLM/H M	
			NBQ	BLMxxBB	MMZxxxxD	BKxxxxLL	
			NBI	BLMxxBA/BC	MMZxxxxF		
	GHz Band	Standard	HFY	BLMxxHG	MMZxxxxA-Z		
		For High Speed Signal	HFV	BLMxxHE		FBMHxxxxH M	
			HFJ	BLMxxHD	MMZxxxxA-Z		
			HFQ	BLMxxHB		FBMHxxxxHL	
		Low DC Resistance	HPY	BLMxxEG		FBMJxxxxHS	

Multilayer Chip Beads & Inductor

Multilayer	Category		Chilisin	Murata	TDK	Taiyoyuden	NIC
Chip Beads	Large Current	Standard	UPB	BLMxxPG	MPZxxxxR	FBMHxxxHS	
			PBY/GBK	BLMxxPG	MPZxxxxS	BKPxxxxHS	
			PBJ	BLMxxPD			
		High Speed Signal	NBP		MPZxxxxD		
		Low DC Resistance	UPB	BLMxxSG		FBMJxxxxHS	
Multilayer Inductor	Standard		CL	LQMxxxx	MLFxxxx	LKxxxx	
	High Frequency		CLH	LQGxx-HN	MLKxxxx MLGxxxx	HKxxxx	
	Power Inductor		MPA/MPB/MPC	LQMxx-PN	MLPxxxx	CKPxxxx	
Thin Film	Standard		TFL	LQPxxM-0x			



Wire Wound Inductor

Wire Wound	Category	Chilisin	Murata	TDK	T.Y.	Coil Craft	TOKO	NIC
Common Mode Choke	USB 2.0	CMM21	DLW21S---SQ	ACM2012		0805USB	NT2012	
		CMM31	DLW31S---SQ			1206USB		
	USB3.0	CMM11			CM01S(H)(U)			
	HDMI	CMHD21	DLW21S-HQ	ACM2012H ACM2012D				
Chip Inductor	General Signal Line	NL				1206CS		
		LS				----LS		
		PS				----PS		
		SQV	LQH--M					
		SQC	LQH--C LQH--D					
	High Frequency	CS	LQW--A			----CS		
		CM	LQW15A_00 LQW18A_00					
		HC				----HC		
		HQ				----HQ		



Wire Wound Inductor

Wire Wound	Category	Chilisin	Murata	TDK	T.Y.	Coil Craft	Cyntec	Vishay	Sumida	NIC
Power Inductor	Shielded	MHCC/MHCI		SPM		XFL	PCMB	IHLP	CDMC	
		LVS	LQH--P	VLS	NRXX		PS/PSI/PL/PLR/PHI	IFSC		
		LVF		VLS			PSE----- PHE----			
		SLPS		VLCF		LPS				
		SCDS				MSS			CDRH	
		SLF		SLF	NS					
	Unshield	SCD						IDCP	CD	
		SSL				DO		IDC		
		SSL-HC				DO----H				
		SDT				DT				
		SDS				DS		IDSC		



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Application - Smart Phone

RF Circuit
(CLH)



(NBQ, SBJ, HFJ)



Analog TV Circuit
(CLH)



(CS)



(CM)



(LD)



(CMM11)



Camera Unit
(SBY, CL, MPB)



DC-DC Converter
(LVS)



(MPB)



(LVF)



Application – Tablet PC

WiFi / Bluetooth

(CLH)  (NBQ, SBJ, HFJ)



Camera Unit

(SBY, CL, MPB)



3G

(CS)



(CLH)



DC-DC Converter

(PBY)



(CMM)



(LVS)



(MHCC)

(LVF)



Back Lighting

(LVS)



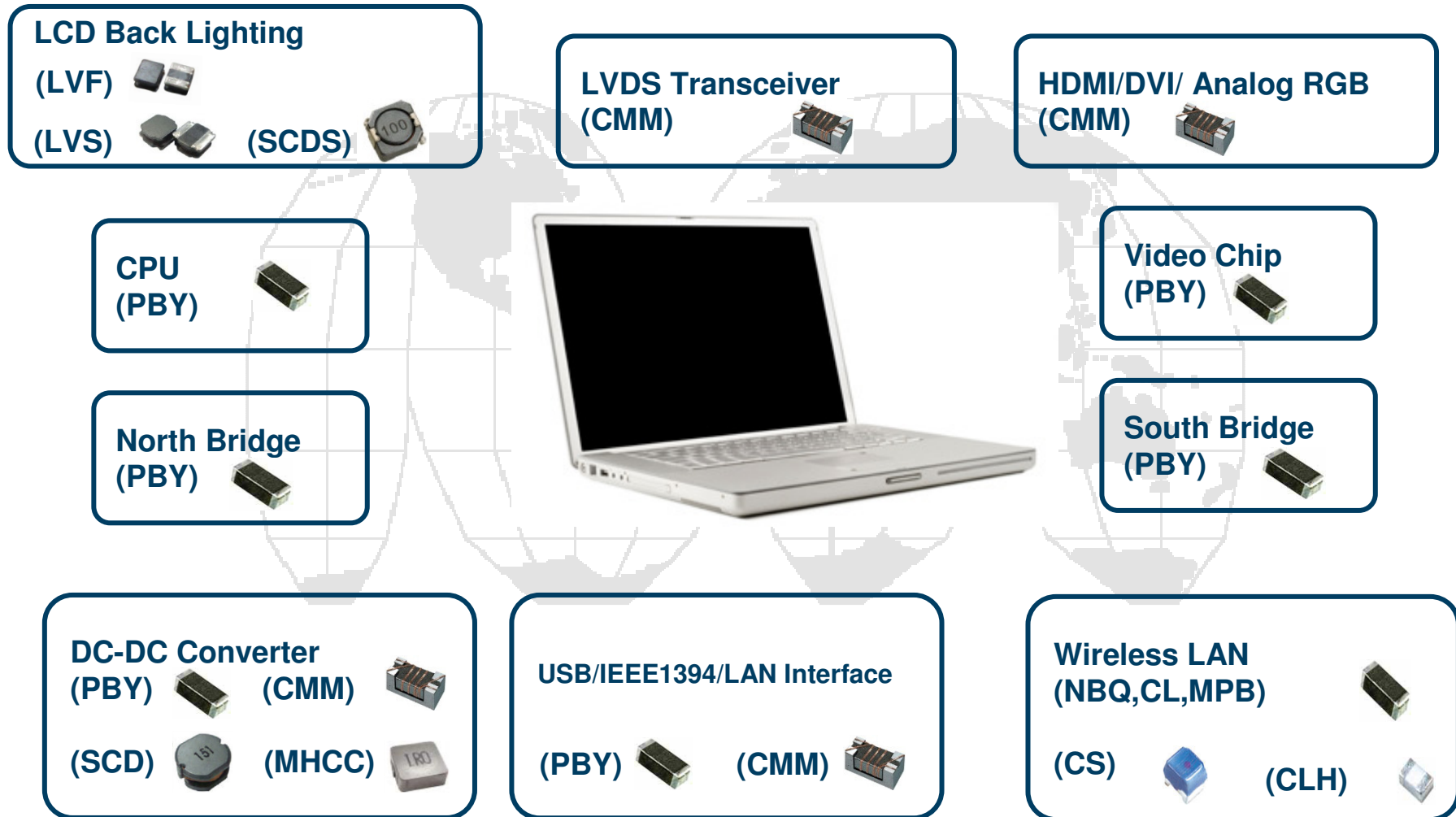
(LVF)



(MPB)



Application – Laptop



Application – All in One

LCD Back Lighting
(LVS) (SCDS)
(LVF)



HDMI/DVI/Analog RGB
(CMM)



Video Chip
(CLH) (PBX)
(CPU) (MHCC)



CPU
(PBX)



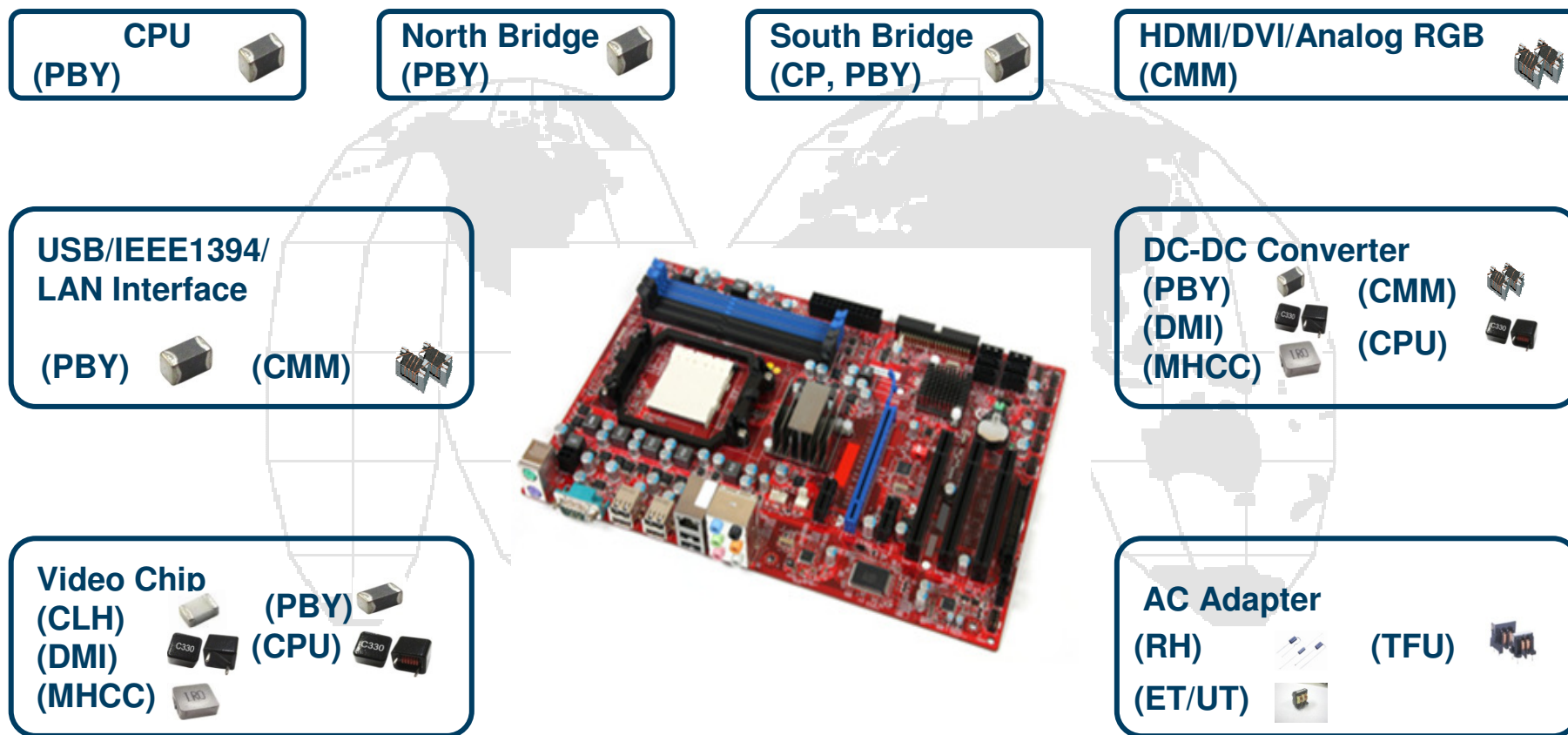
USB/IEEE1394 /LAN Interface
(PBX) (CMM)



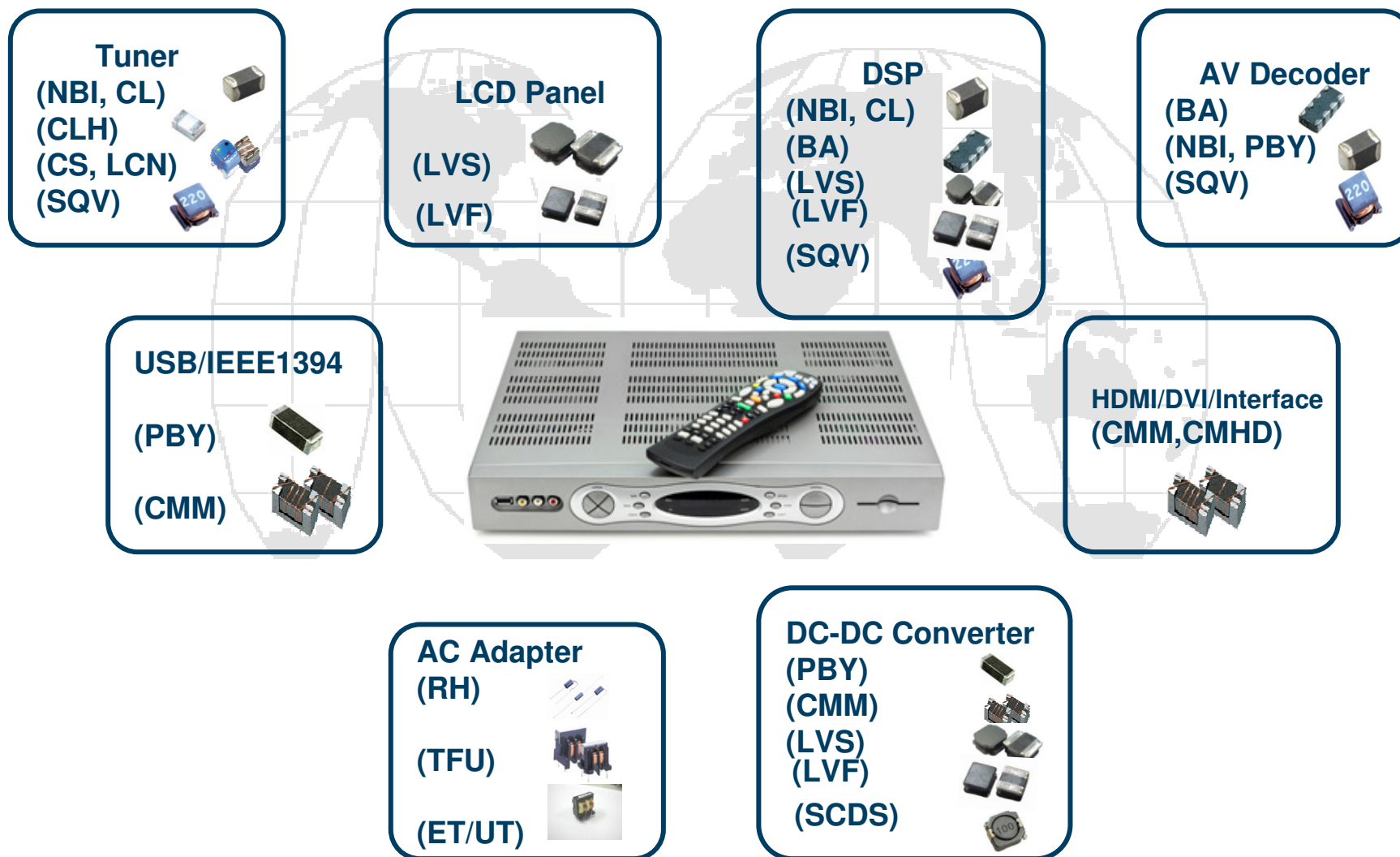
DC-DC Converter
(PBX) (CPU) (MHCC)



Application - Mother Board



Application - STB



Application - DSC



Application - DVD Player



Application - Game Console

CPU

(PBY)



Controller I/F

(NBI)

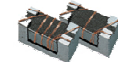


USB/1394/LAN/HDD Interface

(PBY)



(CMM)



Controller

(NBI)

(CMM)

(SLF)

(SCDS)

(LVS)

(RH)

(LVF)



Wireless LAN

(NBQ)

(CLH)

(CL)

(CS,LCN)

(BPF)

(Balun)



AC Adapter

(RH)



(TFU)



(ET/UT)



Graphic Processing

(NBI,NBQ)



DC-DC Converter

(PBY)



(CMM)



(SCDS)



Blu-ray Disc/DVD

(BA)



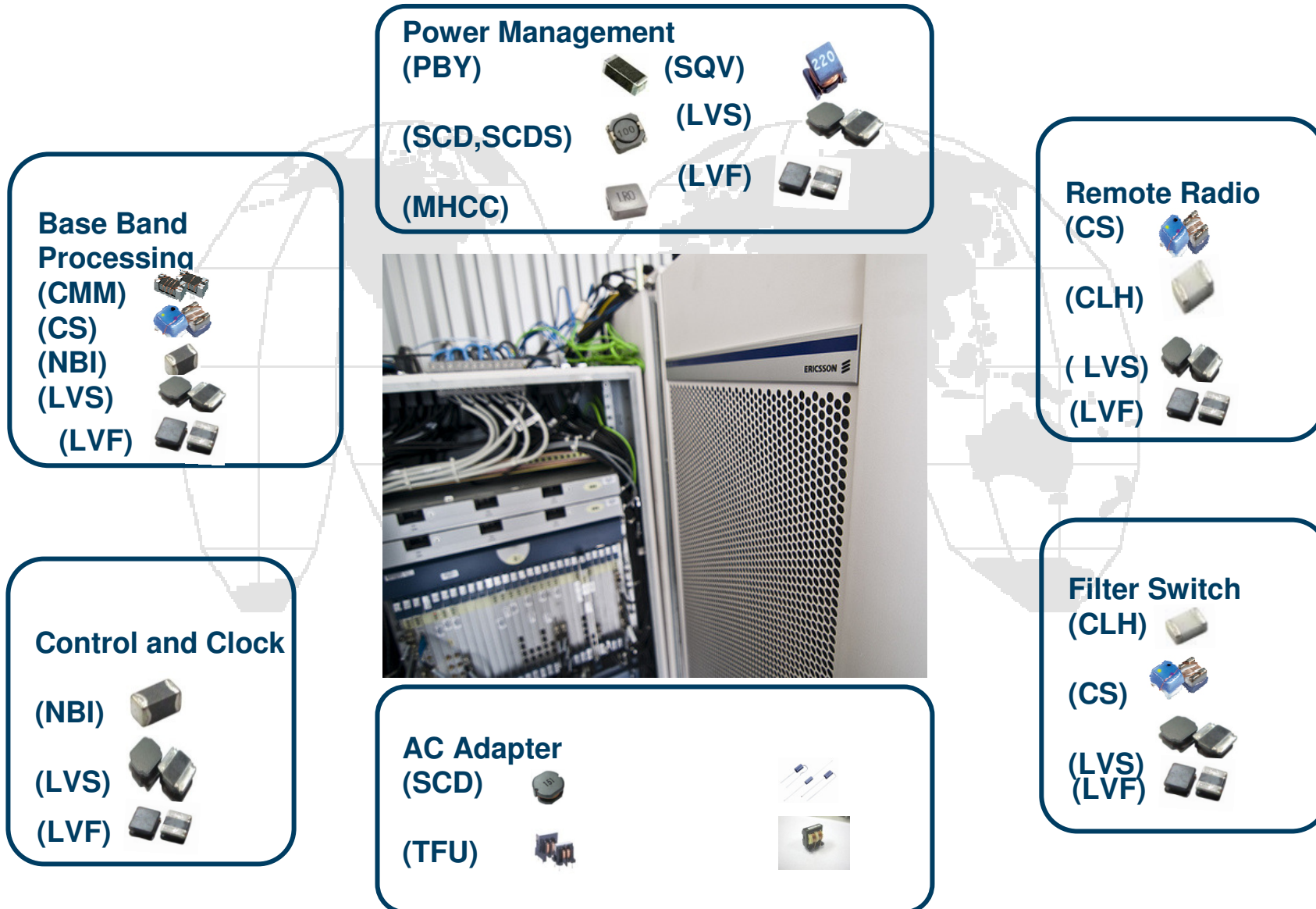
(NBI)



(SQV)



Application - Base Station



Application - LCD TV

Tuner

(NBI, CL)



(CLH)



(SQV)



(CS, LCN)



DSP

(NBI, CL)



(BA)



(SQV)



(LVS)



(LVF)

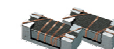


USB/1394/HDMI Interface

(PBY)



(CMM)



AC Adapter (RH)



(TFU)



(ET/UT)



Clock

(NBI)



Memory Card Interface

(NBI)



(CMM)



LCD Back Lighting

(LVF)



(LVS)



(SCDS)



WiFi

(MPB)



DC-DC Converter

(PBY)



(SCDS)



(CMM)



Audio

(LVS)



(LVF)



(SCDS)





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